



An introduction to density functional theory for experimentalists

Prof. Feliciano Giustino
University of Oxford

Paradim School, Cornell, July 2016

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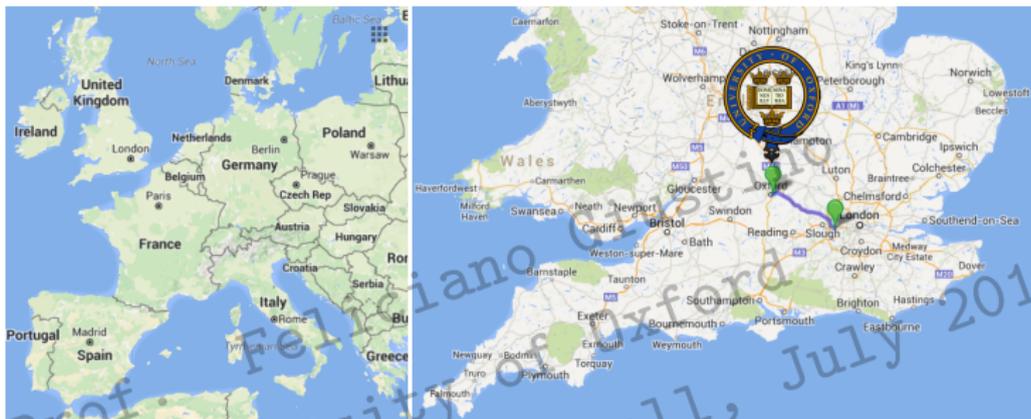
University of Oxford

25–29 July 2016



Lecture 1.1

Ab initio materials modelling



About me



Monday 25 – Friday 29

9:30–10:15	Theory Lecture 1	45 min
10:15–10:45	Coffee Break	30 min
10:45–11:30	Theory Lecture 2	45 min
11:30–13:30	Lunch Break	2 h
13:30–14:15	Practical Lecture	45 min
14:15–14:30	Short Break	15 min
14:30–16:30	Hands-on Session	2 h
18:00–19:30	Dinner	1 h
19:30–21:30	Team Problem Solving Workshops	2 h

Handouts



Lecture 1.1
Ab initio materials modelling

24/16 | Lecture 1.1

F. Giustino

Tutorial Sheets



An introduction to density functional theory for experimentalists
Tutorial 1.1

Login shell and compilation

In order to work on the HPC cluster we need to establish a secure connection. We first open a terminal, and then type:

```
$ ssh -X gustavo2@maec-jhu.edu -i ~/.ssh/tutorial1.temporary.edu
```

where `gustavo2@maec-jhu.edu` must be replaced by the username that you have been assigned. After logging in, you should see something like:

```
[gustavo2@temp01.jhu.edu]login~node04 ~$
```

This is the command line that we will use from now on.

We can customize the "Unix shell" environment by changing the prompt, creating a couple of "aliases", and adding modules that we will need later on. We copy/paste the following into the terminal (it is important to copy/paste exactly as it is, since the `bash` shell is very picky with spaces):

```
cat > ~/.bashrc.nice << EOF
rgrep="
alias cp="cp -i"
alias ll="ls -l"
module load gcc/compilers/3.3.4
module load acrypsides
module load gnuplot/5.0.0
EOF
cat > ~/.bashrc.nice ~/.bashrc > tmp ; mv tmp ~/.bashrc ; source ~/.bashrc
```

Starting from the next login the prompt will be `ll` and the command `c` and `ll` will clear the screen and list the content of a directory, respectively.

We can now create our working directory for this school:

```
$ mkdir scratch/summerchool ; cd ~/scratch/summerchool
```

In this school we will be using the Quantum ESPRESSO (QE) software package.
The website can be found at www.quantum-espresso.org

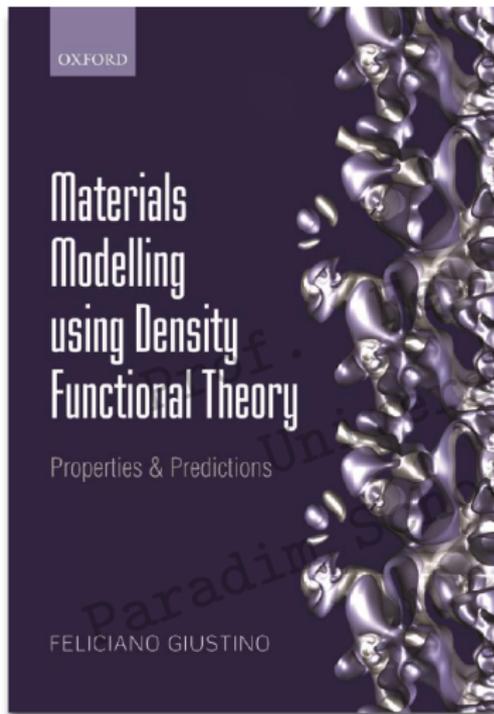


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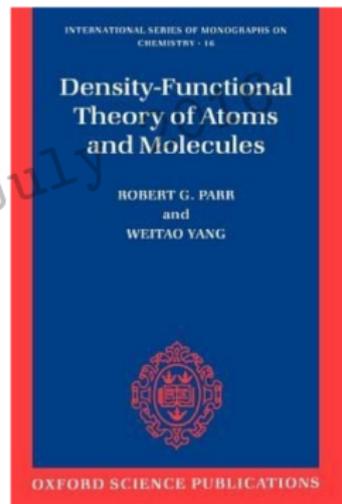
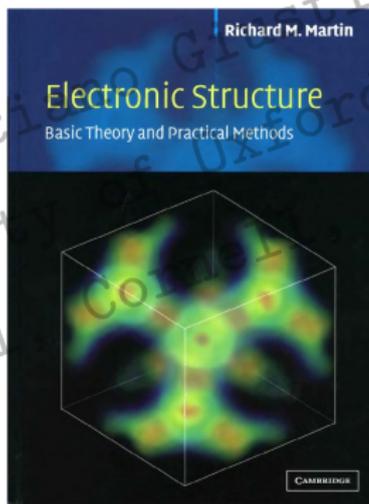
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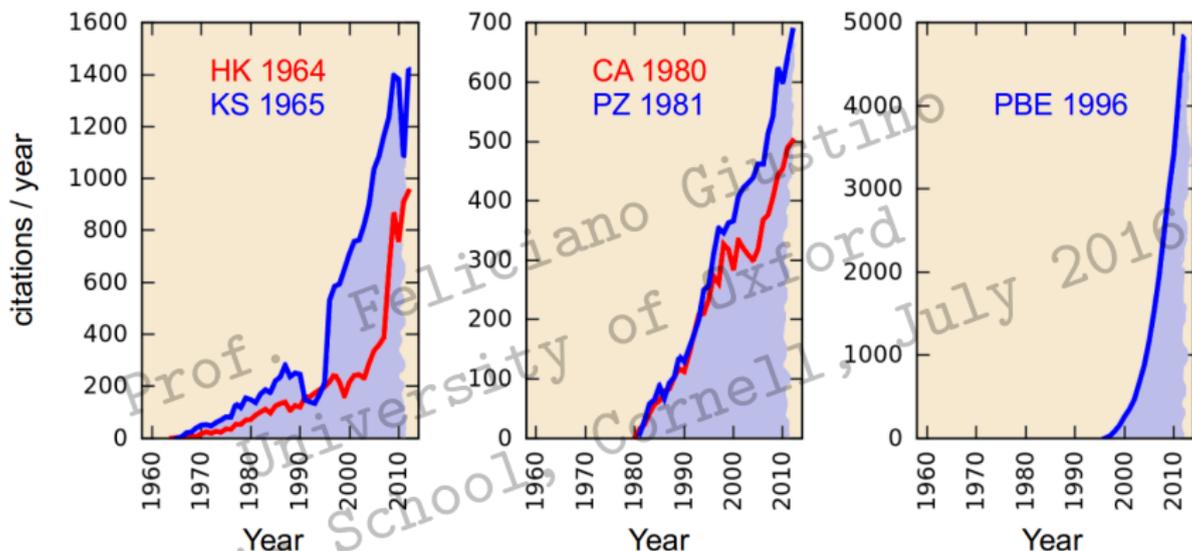
Tutorial 1.1 | 1 of 8

MSc and 1st year PhD level



Advanced PhD level Theoretical foundations





HK 1964

Hohenberg, Kohn, Phys. Rev. 136, B864 (1964)

KS 1965

Kohn, Sham, Phys. Rev. 140, A1133 (1965)

CA 1980

Ceperley, Alder, Phys. Rev. Lett. 45, 566 (1980)

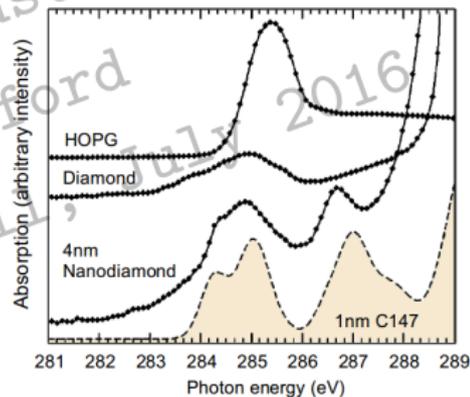
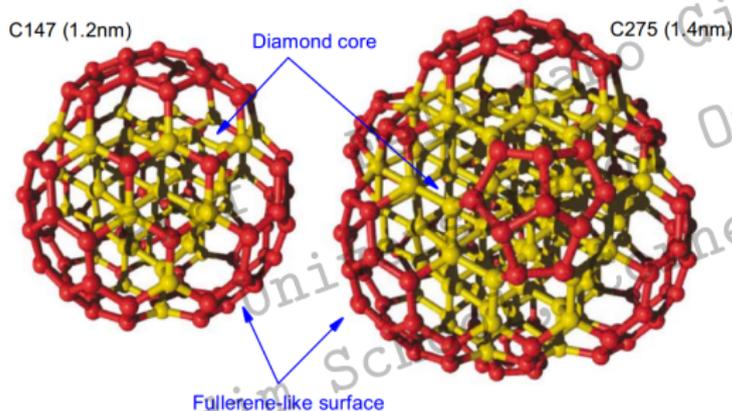
PZ 1981

Perdew, Zunger, Phys. Rev. B 23, 5048 (1981)

PBE 1996

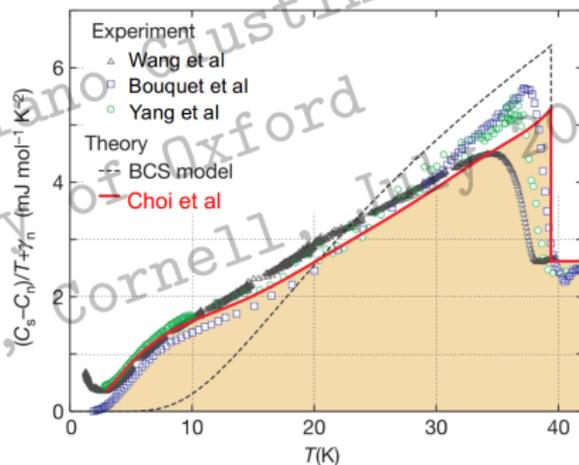
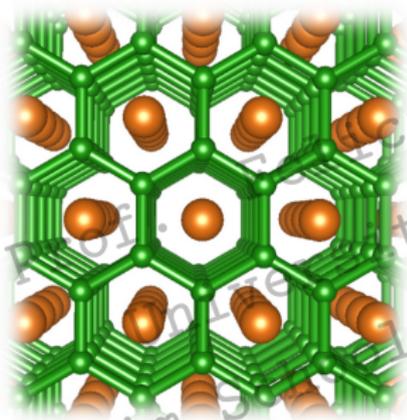
Perdew, Burke, Ernzerhof, Phys. Rev. Lett. 77, 3865 (1996)

Structure of nanodiamonds



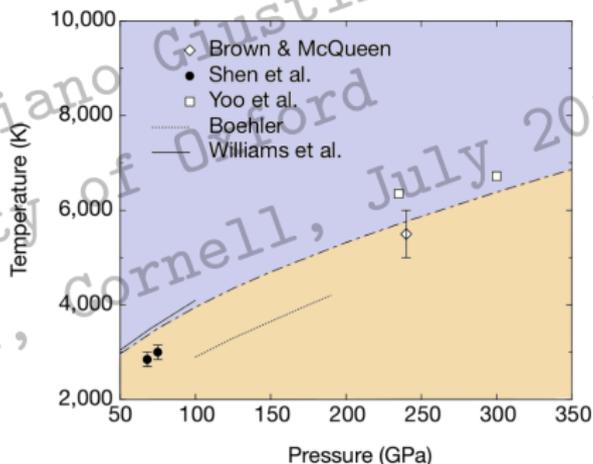
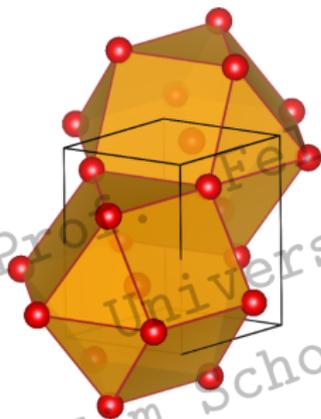
Raty, Galli, Bostedt, van Buuren, Terminello, Phys. Rev. Lett 90, 037401 (2003)

Heat capacity of superconducting MgB_2



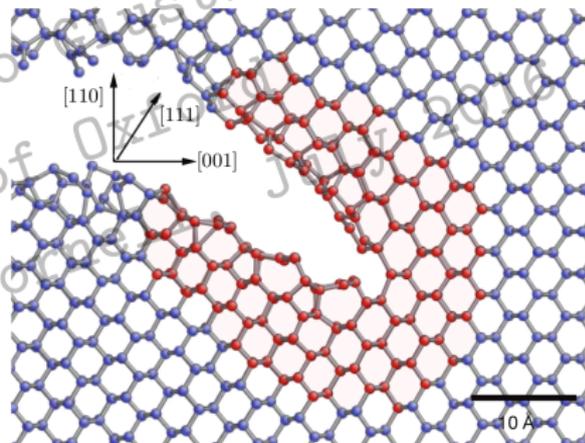
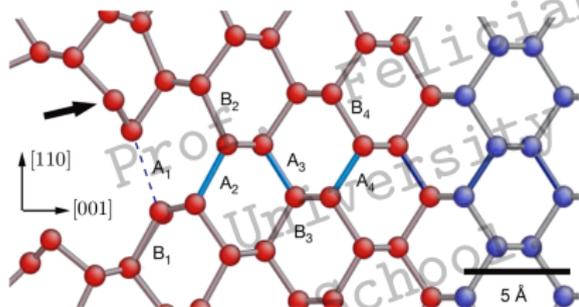
Choi, Roundy, Sun, Cohen, Louie, Nature 418, 758 (2002)

Melting temperature of ϵ -Fe at the core-mantle boundary



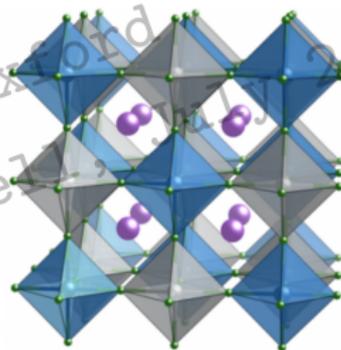
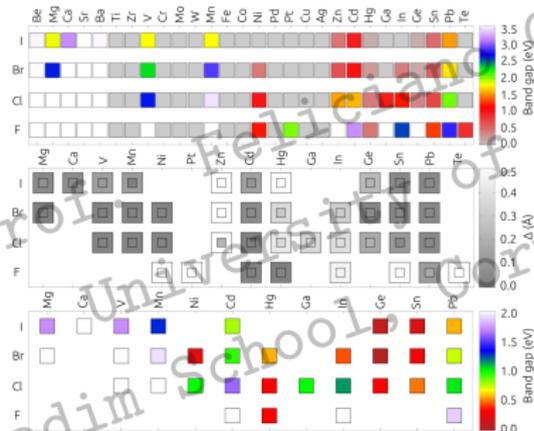
Alfe, Gillan, Price, Nature 401, 462 (1999)

Brittle fracture in silicon



Kermode et al, Nature 455, 1224 (2008)

Rational design of halide perovskites



Filip, Giustino, J. Phys. Chem. C, 120, 166 (2016)

Volonakis, Filip, Haghighirad, Sakai, Wenger, Snaith, Giustino, JPC Lett. 7, 1254 (2016)

Rational design of halide perovskites



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- 1964** Hohenberg–Kohn theorem and Kohn–Sham formulation
- 1972** Relativistic extension of density functional theory
- 1980** Local density approximation for exchange and correlation
- 1984** Time-dependent density functional theory
- 1985** First-principles molecular dynamics
- 1986** Quasiparticle corrections for insulators
- 1987** Density functional perturbation theory
- 1988** Towards quantum chemistry accuracy
- 1991** Hubbard-corrected density functional theory
- 1996** The generalized gradient approximation

Exponential rate of progress in the past two decades...

- **Transferability**

We can use the same code/methods for very different materials

- **Simplicity**

The Kohn-Sham equations are the closest thing to the usual Schrödinger equation that we can think of

- **Reliability**

Often we can predict materials properties with high accuracy, sometimes even before the actual experiment

- **Software sharing**

The development of DFT has become a global enterprise, eg open source and collaborative software development

- **Reasonable starting point**

Often the shortcomings of DFT can be cured by using more sophisticated approaches, which still use DFT as their starting point



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Lecture 1.2

Many-body problem

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July 2016

Materials = Electrons + Nuclei

- Schrödinger equation for the H atom
(nucleus at $\mathbf{r} = 0$)

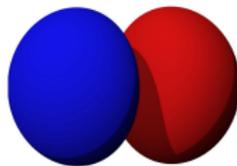
$$-\frac{\hbar^2}{2m_e} \nabla^2 \psi(\mathbf{r}) - \frac{e^2}{4\pi\epsilon_0} \frac{1}{|\mathbf{r}|} \psi(\mathbf{r}) = E_{\text{tot}} \psi(\mathbf{r})$$

- wavefunctions of H

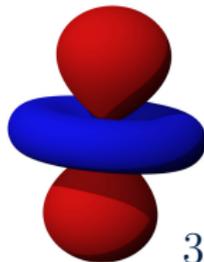
[from Wikipedia]



1s



2p_x



3d_{z²}

- Many-body wavefunction (to fix ideas: only 3 electrons)

$$\psi(\mathbf{r}) \rightarrow \Psi = \Psi(\mathbf{r}_1, \mathbf{r}_2, \mathbf{r}_3)$$

- Probability of finding electron #1 at the point \mathbf{r}

$$\text{prob}(\mathbf{r}_1 = \mathbf{r}) = \int |\Psi(\mathbf{r}, \mathbf{r}_2, \mathbf{r}_3)|^2 d\mathbf{r}_2 d\mathbf{r}_3$$

- Electron density at the point \mathbf{r}

$$n(\mathbf{r}) = \text{prob}(\mathbf{r}_1 = \mathbf{r}) + \text{prob}(\mathbf{r}_2 = \mathbf{r}) + \text{prob}(\mathbf{r}_3 = \mathbf{r})$$

- Electrons are indistinguishable

$$n(\mathbf{r}) = 3 \int |\Psi(\mathbf{r}, \mathbf{r}_2, \mathbf{r}_3)|^2 d\mathbf{r}_2 d\mathbf{r}_3$$

$$(\text{kinetic energy} + \text{potential energy}) \Psi = E_{\text{tot}} \Psi$$

- kinetic energy, electrons and nuclei

$$-\sum_{i=1}^N \frac{\hbar^2}{2m_e} \nabla_i^2 - \sum_{I=1}^M \frac{\hbar^2}{2M_I} \nabla_I^2$$

- potential energy, electron-electron repulsion

$$\frac{1}{2} \sum_{i \neq j} \frac{e^2}{4\pi\epsilon_0 |\mathbf{r}_i - \mathbf{r}_j|}$$

- potential energy, nucleus-nucleus repulsion

$$\frac{1}{2} \sum_{I \neq J} \frac{e^2}{4\pi\epsilon_0} \frac{Z_I Z_J}{|\mathbf{R}_I - \mathbf{R}_J|}$$

- potential energy, electron-nucleus attraction

$$-\sum_{i,I} \frac{e^2}{4\pi\epsilon_0} \frac{Z_I}{|\mathbf{r}_i - \mathbf{R}_I|}$$

$$\left[-\sum_i \frac{\hbar^2}{2m_e} \nabla_i^2 - \sum_I \frac{\hbar^2}{2M_I} \nabla_I^2 + \frac{1}{2} \sum_{i \neq j} \frac{e^2}{4\pi\epsilon_0 |\mathbf{r}_i - \mathbf{r}_j|} + \frac{1}{2} \sum_{I \neq J} \frac{e^2}{4\pi\epsilon_0 |\mathbf{R}_I - \mathbf{R}_J|} - \sum_{i,I} \frac{e^2}{4\pi\epsilon_0 |\mathbf{r}_i - \mathbf{R}_I|} \right] \Psi = E_{\text{tot}} \Psi$$

Hartree atomic units

- masses in units of m_e (electron mass)
- lengths in units of a_0 (Bohr radius)
- energies in units of $e^2/4\pi\epsilon_0 a_0$ (Hartree)

$$\left[\sum_i \frac{1}{2} \nabla_i^2 - \sum_I \frac{1}{2M_I} \nabla_I^2 + \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} + \frac{1}{2} \sum_{I \neq J} \frac{Z_I Z_J}{|\mathbf{R}_I - \mathbf{R}_J|} - \sum_{i,I} \frac{Z_I}{|\mathbf{r}_i - \mathbf{R}_I|} \right] \Psi = E_{\text{tot}} \Psi$$

Many-body Schrödinger equation



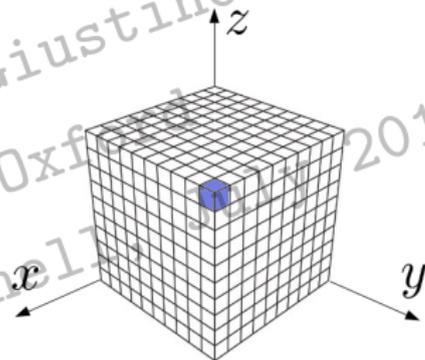
MBSE



MBSE in Hartree units

Storage requirements for the many-body wavefunction of a unit cell of silicon (diamond structure)

- $\Delta x \sim 0.1 \text{ \AA}$
- $a = 5.43 \text{ \AA}$
- $N_p = (a^3/4)/(\Delta x)^3 \sim 40,000$
- 8 valence electrons per unit cell
- $\Psi = 40,000^8$ complex numbers



10^{26} Terabytes

Set nuclear masses $M_I = \infty$:

$$\left[-\sum_i \frac{1}{2} \nabla_i^2 - \sum_I \frac{1}{2M_I} \nabla_I^2 + \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} + \frac{1}{2} \sum_{I \neq J} \frac{Z_I Z_J}{|\mathbf{R}_I - \mathbf{R}_J|} - \sum_{i,I} \frac{Z_I}{|\mathbf{r}_i - \mathbf{R}_I|} \right] \Psi = E_{\text{tot}} \Psi$$

$$\left[-\sum_i \frac{\nabla_i^2}{2} + \sum_i V_n(\mathbf{r}_i) + \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} \right] \Psi = E \Psi$$

Electronic structure theory in a nutshell

- Independent particle Hamiltonian

$$\hat{H}_0(\mathbf{r}) = -\frac{1}{2}\nabla^2 + V_n(\mathbf{r})$$

- Independent particles + Coulomb

$$\sum_i \hat{H}_0(\mathbf{r}_i) \Psi(\mathbf{r}_1, \dots, \mathbf{r}_N) + \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} \Psi(\mathbf{r}_1, \dots, \mathbf{r}_N) = E \Psi(\mathbf{r}_1, \dots, \mathbf{r}_N)$$

- If we neglect this electron-electron Coulomb repulsion, then electrons will not 'feel' each other \rightarrow **probability of independent events**

$$\Psi(\mathbf{r}_1, \mathbf{r}_2, \dots, \mathbf{r}_N) = \phi_1(\mathbf{r}_1) \cdots \phi_N(\mathbf{r}_N)$$

$$\hat{H}_0(\mathbf{r}) \phi_i(\mathbf{r}) = \varepsilon_i \phi_i(\mathbf{r})$$

$$\sum_i \hat{H}_0(\mathbf{r}_i) \Psi(\mathbf{r}_1, \dots, \mathbf{r}_N) = E \Psi(\mathbf{r}_1, \dots, \mathbf{r}_N)$$

$$E = \varepsilon_1 + \cdots + \varepsilon_N$$

Example: Ground state of He

- Independent particle equation ($Z = 2$)

$$-\frac{1}{2}\nabla^2\phi(\mathbf{r}) - \frac{2}{|\mathbf{r}|}\phi(\mathbf{r}) = \varepsilon\phi(\mathbf{r})$$

- Lowest-energy solution

$$\phi_{1s}(\mathbf{r}) = \frac{2^{3/2}}{\sqrt{\pi}}\exp(-2|\mathbf{r}|) \quad \text{with} \quad E_{1s} = -\frac{2^2}{2}$$

- Ground-state many-body wavefunction in the *independent-electrons approximation*

$$\Psi(\mathbf{r}_1, \mathbf{r}_2) = \phi_{1s}(\mathbf{r}_1)\phi_{1s}(\mathbf{r}_2) = \frac{8}{\pi}\exp[-2(|\mathbf{r}_1| + |\mathbf{r}_2|)]$$

- Ground-state energy in the *independent-electrons approximation*

$$E = 2E_{1s} = -4 \text{ Ha} = -108.8 \text{ eV}$$

		2 He Helium 4.00
8 O Oxygen 16.00	9 F Fluorine 19.00	10 Ne Neon 20.18
16 S Sulfur 32.07	17 Cl Chlorine 35.45	18 Ar Argon 39.95

- Let us calculate the electron density for 2 electrons in the independent-electron approximation

$$n(\mathbf{r}) = 2 \int |\Psi(\mathbf{r}, \mathbf{r}_2)|^2 d\mathbf{r}_2 = 2 \int |\phi_1(\mathbf{r})|^2 |\phi_2(\mathbf{r}_2)|^2 d\mathbf{r}_2 = 2 |\phi_1(\mathbf{r})|^2$$

- Admissible wavefunctions must be *antisymmetric* w.r.t. exchange of space/spin variables. 'Slater determinant' for a spin-compensated system

$$\Psi(\mathbf{r}_1, \mathbf{r}_2) = \frac{1}{\sqrt{2}} [\phi_1(\mathbf{r}_1)\phi_2(\mathbf{r}_2) - \phi_1(\mathbf{r}_2)\phi_2(\mathbf{r}_1)]$$

- Let us try the density again

$$n(\mathbf{r}) = 2 \int |\Psi(\mathbf{r}, \mathbf{r}_2)|^2 d\mathbf{r}_2 = |\phi_1(\mathbf{r})|^2 + |\phi_2(\mathbf{r})|^2$$

- The electron density can be used to determine the **electrostatic** field generated by the electrons

$$\left[-\frac{1}{2}\nabla^2 + V_n(\mathbf{r}) \right] \phi_i(\mathbf{r}) = \varepsilon_i \phi_i(\mathbf{r})$$

$$n(\mathbf{r}) = \sum_i |\phi_i(\mathbf{r})|^2$$

$$V_H(\mathbf{r}) = \int d\mathbf{r}' \frac{n(\mathbf{r}')}{|\mathbf{r}-\mathbf{r}'|}$$

$$\left[-\frac{1}{2}\nabla^2 + V_n(\mathbf{r}) + V_H(\mathbf{r}) \right] \phi'_i(\mathbf{r}) = \varepsilon'_i \phi'_i(\mathbf{r})$$

- This is Hartree's **self-consistent field approximation** (1928)

Advantages

No need for the many-body wavefunction

Shortcomings

Requires iterative solution

- The Hartree approximation does not incorporate the **constraint** on the antisymmetry of the many-body wavefunction, $\Psi(\mathbf{r}_2, \mathbf{r}_1) = -\Psi(\mathbf{r}, \mathbf{r}_2)$
- Incorporating this constraint in the mean-field equation leads to a new potential energy contribution, the **Fock exchange**

[Sec. 2.8 and App. A of book]

$$\left[-\frac{\nabla^2}{2} + V_n(\mathbf{r}) + V_H(\mathbf{r}) \right] \phi_i(\mathbf{r}) + \int d\mathbf{r}' V_X(\mathbf{r}, \mathbf{r}') \phi_i(\mathbf{r}') = \varepsilon_i \phi_i(\mathbf{r})$$

$$V_X(\mathbf{r}, \mathbf{r}') = - \sum_{j \in \text{occ}} \frac{\phi_j^*(\mathbf{r}') \phi_j(\mathbf{r})}{|\mathbf{r} - \mathbf{r}'|}$$

- The Fock potential 'enforces' Pauli's principle by making sure that
 - same-spin electrons repel each other
 - opposite-spin electrons attract each other
- The Fock potential is **non-local**

- So far we assumed that electrons are independent, that is *uncorrelated*

$$\text{prob}(\mathbf{r}_1, \mathbf{r}_2) = \text{prob}(\mathbf{r}_1) \times \text{prob}(\mathbf{r}_2)$$

- This is not true since electrons do repel each other, therefore the 'true' wavefunction cannot be expressed as a Slater determinant

$$\Psi_{\text{true}}(\mathbf{r}_1, \mathbf{r}_2) \neq \frac{1}{\sqrt{2}} [\phi_1(\mathbf{r}_1)\phi_2(\mathbf{r}_2) - \phi_1(\mathbf{r}_2)\phi_2(\mathbf{r}_1)]$$

- Since the Slater determinant is really useful for practical calculations, we keep using it, but we **pay the price** of adding yet another potential

$$\left[-\frac{1}{2} \nabla^2 + V_n + V_H + V_X + V_C \right] \phi_i = \varepsilon_i \phi_i$$

↑
correlation
potential

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Example: Ground state of He

		2 He Helium 4.00
8 O Oxygen 16.00	9 F Fluorine 19.00	10 Ne Neon 20.18
16 S Sulfur 32.07	17 Cl Chlorine 35.45	18 Ar Argon 39.95

Kinetic energy + electron-nucleus interaction	-3.89 Ha	-105.8 eV
Hartree energy	+2.05 Ha	+55.8 eV
Fock exchange energy	-1.02 Ha	-27.8 eV
Correlation energy	-0.04 Ha	-1.1 eV
<hr/>		
Total energy	-2.90 Ha	-78.9 eV

$$\left[-\frac{1}{2} \nabla^2 + V_n + V_H + V_{xc} \right] \phi_i = \epsilon_i \phi_i$$

↑
Exchange and Correlation



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Lecture 2.1

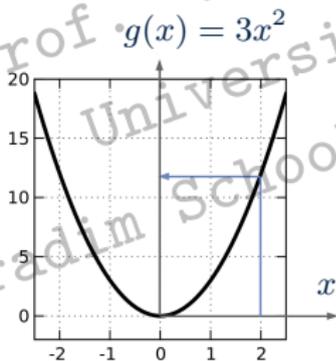
Density-functional theory

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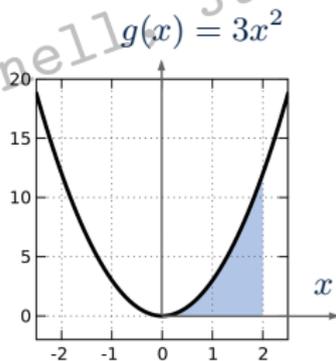
Density Functional Theory = theory about the energy of electrons being a functional of their density

Function



$$g(2) = 12$$

Functional



$$F[g] = \int_0^2 dx g(x) = 8$$

The total energy is a functional of the wavefunction

$$\hat{H} \Psi = E \Psi \longrightarrow E = \int d\mathbf{r}_1 \dots d\mathbf{r}_N \Psi^*(\mathbf{r}_1, \dots, \mathbf{r}_N) \hat{H} \Psi(\mathbf{r}_1, \dots, \mathbf{r}_N)$$

So for a generic quantum state we have

$$\Psi(\mathbf{r}_1, \dots, \mathbf{r}_N) \longrightarrow E \qquad E = E[\Psi(\mathbf{r}_1, \dots, \mathbf{r}_N)]$$

Hohenberg and Kohn (1964) discovered that, if we are talking about the lowest-energy state, we also have

$$n(\mathbf{r}) \longrightarrow E \qquad E = E[n(\mathbf{r})]$$

The total energy is a functional of the density

In Lecture 1.2 we had:

$$\left[-\sum_i \frac{\nabla_i^2}{2} + \sum_i V_n(\mathbf{r}_i) + \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} \right] \Psi = E \Psi$$

In order to prove the HK theorem we rewrite the energy more compactly

$$E = \int d\mathbf{r} n(\mathbf{r}) V_n(\mathbf{r}) + \langle \Psi | \hat{U} | \Psi \rangle, \quad \hat{U} = -\sum_i \frac{\nabla_i^2}{2} + \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|}$$

Now we want to show the following

Theorem

In the ground-state, the electron density $n(\mathbf{r})$ uniquely determines the external potential $V_n(\mathbf{r})$

- Assume there are two potentials V_1 and V_2 for the same density
[For clarity we temporarily suppress the subscript 'n' in V_n]
- By solving the MBSE for each potential we find the lowest-energy states E_1, Ψ_1 and E_2, Ψ_2 , respectively
- Since Ψ_1 **is** the ground state of V_1 we have

$$\int nV_1 + \langle \Psi_1 | \hat{U} | \Psi_1 \rangle = E_1$$

- Since Ψ_1 **is not** the ground state of V_2 we have

$$\int nV_2 + \langle \Psi_1 | \hat{U} | \Psi_1 \rangle > E_2$$

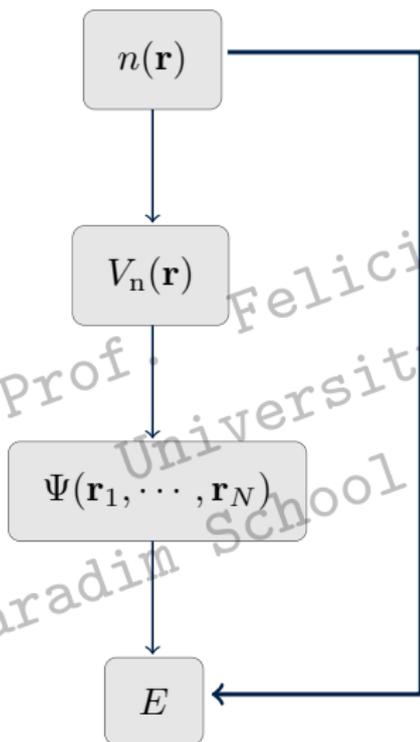
- The difference gives

$$\int n(V_1 - V_2) > E_1 - E_2$$

- By repeating the same argument starting from Ψ_2 we have

$$\int n(V_2 - V_1) > E_2 - E_1$$

- The sum of the last two equations yields the contradiction $0 > 0$



HK theorem

In the ground-state the electron density $n(\mathbf{r})$ uniquely determines the total energy E .

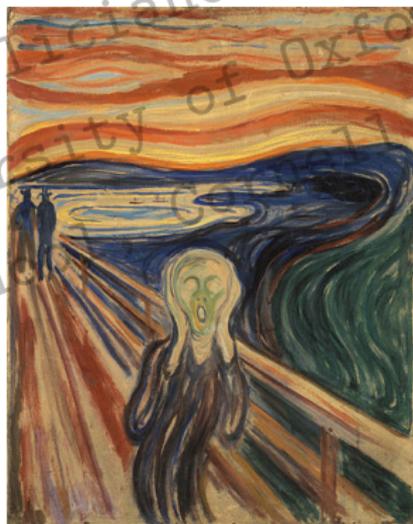
HK variational principle

Any $n'(\mathbf{r}) \neq n(\mathbf{r})$ yields $V' \neq V$ and $\Psi' \neq \Psi$, therefore $E' > E$.

The HK theorem states that, in the ground state, the total energy of many electrons is a functional of their density, $E = E[n(\mathbf{r})]$.

But what is the form of this functional?

The energy functional is unknown



The scream by E. Munch (1910)

$$E[n] = \underbrace{\int d\mathbf{r} n(\mathbf{r}) V_n(\mathbf{r})}_{\text{External potential}} + \underbrace{\frac{1}{2} \int d\mathbf{r} d\mathbf{r}' \frac{n(\mathbf{r})n(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|}}_{\text{Hartree energy}} + \boxed{\text{Everything Else}}$$

Kohn and Sham (1965) proposed to

- (1) express the electron density **as if** we had a system of independent electrons

$$n(\mathbf{r}) = \sum_{i \in \text{occ}} |\phi_i(\mathbf{r})|^2$$

- (2) isolate the kinetic energy of these independent electrons from the 'Everything Else' above

$$\boxed{\text{Everything Else}} = - \sum_i \int d\mathbf{r} \phi_i^*(\mathbf{r}) \frac{\nabla^2}{2} \phi_i(\mathbf{r}) + \boxed{\text{Unknown Terms}}$$

Exchange and Correlation

E_{xc}

Total energy

$$E[n] = \int d\mathbf{r} n(\mathbf{r})V_n(\mathbf{r}) + \frac{1}{2} \int d\mathbf{r}d\mathbf{r}' \frac{n(\mathbf{r})n(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} - \sum_i \int d\mathbf{r} \phi_i^*(\mathbf{r}) \frac{\nabla^2}{2} \phi_i(\mathbf{r}) + E_{xc}[n]$$

We find the lowest energy state by looking for stationary points of $E[n]$
[the derivation can be found in Appendix B of the book]

$$\begin{cases} \frac{\delta E}{\delta n} = 0 \\ \langle \phi_i | \phi_j \rangle = \delta_{ij} \end{cases}$$

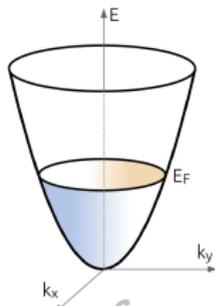
This leads to the Kohn-Sham equations

$$\left[-\frac{1}{2} \nabla^2 + V_n(\mathbf{r}) + V_H(\mathbf{r}) + V_{xc}(\mathbf{r}) \right] \phi_i(\mathbf{r}) = \varepsilon_i \phi_i(\mathbf{r})$$

$$V_{xc} = \frac{\delta E_{xc}}{\delta n}$$

Exchange and Correlation Potential

Homogeneous electron gas

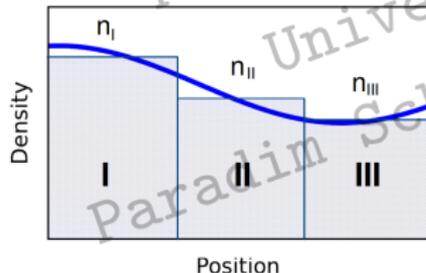


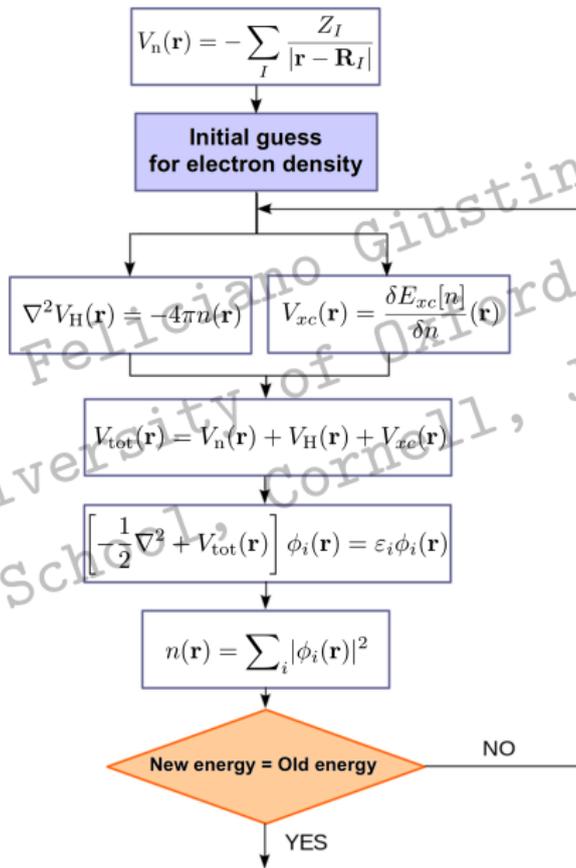
$$n(\mathbf{r}) = \text{constant}$$

$$E_x^{\text{HEG}} = -\frac{3}{4} \left(\frac{3}{\pi} \right)^{\frac{1}{3}} n^{\frac{4}{3}} V$$

$$E_x^{\text{LDA}} = \int_V \frac{E_x^{\text{HEG}}[n(\mathbf{r})]}{V} d\mathbf{r} = -\frac{3}{4} \left(\frac{3}{\pi} \right)^{\frac{1}{3}} \int_V n^{\frac{4}{3}}(\mathbf{r}) d\mathbf{r}$$

$$V_x^{\text{LDA}} = \frac{\delta E_x^{\text{LDA}}}{\delta n} = -\left(\frac{3}{\pi} \right)^{\frac{1}{3}} n^{\frac{1}{3}}(\mathbf{r})$$





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Successes and failures

1																	18					
1A																	8A					
1	H Hydrogen 1.01																	He Helium 4.00				
2	Li Lithium 6.94	Be Beryllium 9.01															B Boron 10.81	C Carbon 12.01	N Nitrogen 14.01	O Oxygen 16.00	F Fluorine 19.00	Ne Neon 20.18
3	Na Sodium 22.99	Mg Magnesium 24.31	3	4	5	6	7	8	9	10	11	12	Al Aluminum 26.98	Si Silicon 28.09	P Phosphorus 30.97	S Sulfur 32.07	Cl Chlorine 35.45	Ar Argon 39.95				
4	K Potassium 39.10	Ca Calcium 40.08	Sc Scandium 44.96	Ti Titanium 47.87	V Vanadium 50.94	Cr Chromium 52.00	Mn Manganese 54.94	Fe Iron 55.85	Co Cobalt 58.93	Ni Nickel 58.69	Cu Copper 63.55	Zn Zinc 65.39	Ga Gallium 69.72	Ge Germanium 72.61	As Arsenic 74.92	Se Selenium 78.96	Br Bromine 79.90	Kr Krypton 83.80				
5	Rb Rubidium 85.47	Sr Strontium 87.62	Y Yttrium 88.91	Zr Zirconium 91.22	Nb Niobium 92.91	Mo Molybdenum 95.94	Tc Technetium (98)	Ru Ruthenium 101.07	Rh Rhodium 102.91	Pd Palladium 106.42	Ag Silver 107.87	Cd Cadmium 112.41	In Indium 114.82	Sn Tin 118.71	Sb Antimony 121.76	Te Tellurium 127.60	I Iodine 126.90	Xe Xenon 131.29				
6	Cs Cesium 132.91	Ba Barium 137.33	La Lanthanum 138.91	Hf Hafnium 178.49	Ta Tantalum 180.95	W Tungsten 183.84	Re Rhenium 186.21	Os Osmium 190.23	Ir Iridium 192.22	Pt Platinum 195.08	Au Gold 196.97	Hg Mercury 200.59	Tl Thallium 204.38	Pb Lead 207.2	Bi Bismuth 208.98	Po Polonium (209)	At Astatine (210)	Rn Radon (222)				
7	Fr Francium (223)	Ra Radium (226)	Ac Actinium (227)	Rf Rutherfordium (261)	Db Dubnium (262)	Sg Seaborgium (266)	Bh Bohrium (264)	Hs Hassium (269)	Mt Meitnerium (268)													

58	59	60	61	62	63	64	65	66	67	68	69	70	71
Ce Cerium 140.12	Pr Praseodymium 140.91	Nd Neodymium 144.24	Pm Promethium (145)	Sm Samarium 150.36	Eu Europium 151.96	Gd Gadolinium 157.25	Tb Terbium 158.93	Dy Dysprosium 162.50	Ho Holmium 164.93	Er Erbium 167.26	Tm Thulium 168.93	Yb Ytterbium 173.04	Lu Lutetium 174.97
90	91	92	93	94	95	96	97	98	99	100	101	102	103
Th Thorium 232.04	Pa Protactinium 231.04	U Uranium 238.03	Np Neptunium (237)	Pu Plutonium (244)	Am Americium (243)	Cm Curium (247)	Bk Berkelium (247)	Cf Californium (251)	Es Einsteinium (252)	Fm Fermium (257)	Md Mendelevium (258)	No Nobelium (259)	Lr Lawrencium (262)



An introduction to density functional theory for experimentalists

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University of Oxford

Paradim School, Cornell, July 2016

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25–29 July 2016



Lecture 2.2

Planewaves and pseudopotentials

DFT calculations require the numerical solution of the KS equations

$$-\frac{1}{2}\nabla^2\phi_i(\mathbf{r}) + V_{\text{tot}}(\mathbf{r})\phi_i(\mathbf{r}) = \epsilon_i\phi_i(\mathbf{r})$$

2nd order PDE \longrightarrow for every y and z we need 2 boundary conditions on x

- **Localized system**

atom | molecule | nanocrystal

$$\phi_i(x, y, z) = 0 \text{ for } x = -\infty, \quad \phi_i(x, y, z) = 0 \text{ for } x = +\infty$$

- **Extended system**

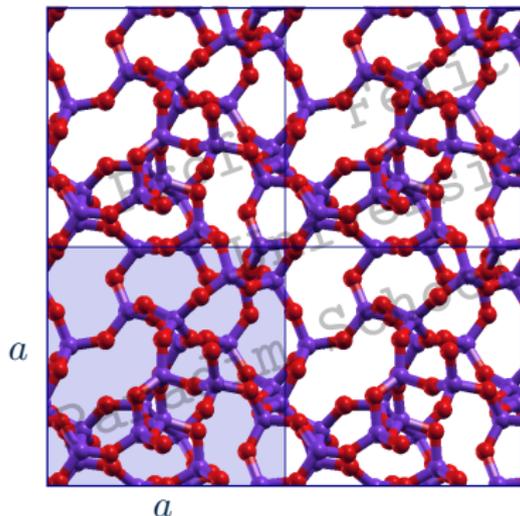
solid | liquid

$$\phi_i(x + a, y, z) = \phi_i(x, y, z), \quad \nabla\phi_i(x + a, y, z) = \nabla\phi_i(x, y, z)$$

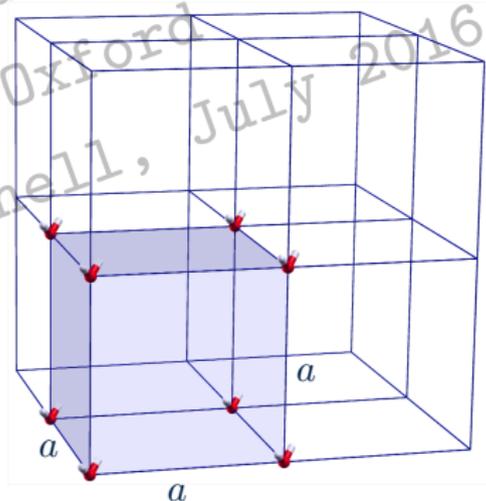
Periodic (BvK) boundary conditions

DFT calculations for **solids**, **liquids**, **interfaces**, and **nanostructures** are performed using BvK boundary conditions

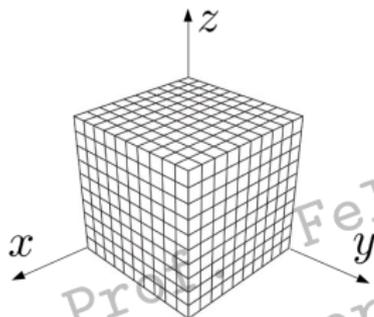
amorphous SiO_2



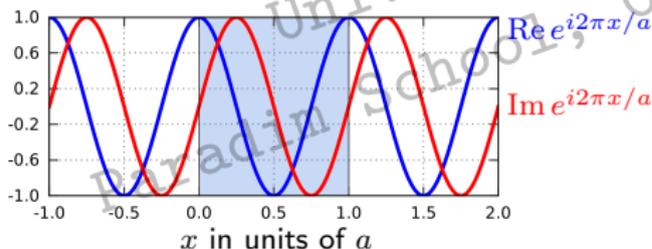
H_2O molecule



A convenient way of handling the KS wavefunctions is by expanding them in a basis of **planewaves** \longrightarrow standard Fourier transform



1D case $\phi(x) = \sum_{n=-\infty}^{+\infty} c_n e^{i2\pi nx/a}$



BvK conditions built in

$$\phi(x+a) = \phi(x)$$

$$\nabla\phi(x+a) = \nabla\phi(x)$$

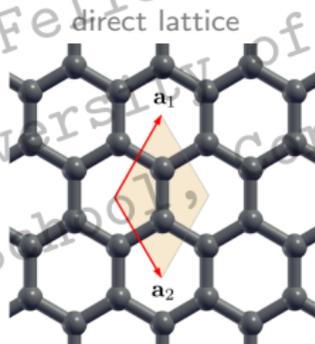
In 2D and 3D we replace $2\pi/a$ by the primitive vectors of the reciprocal lattice, eg

$$\mathbf{b}_1 = 2\pi \frac{\mathbf{a}_2 \times \mathbf{a}_3}{\mathbf{a}_1 \cdot \mathbf{a}_2 \times \mathbf{a}_3}$$

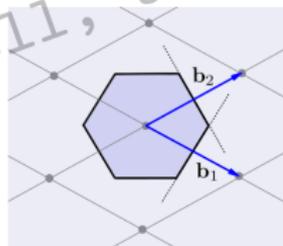
Reciprocal lattice vectors

$$\mathbf{G} = m_1 \mathbf{b}_1 + m_2 \mathbf{b}_2 + m_3 \mathbf{b}_3, \text{ with } m_1, m_2, m_3 \text{ integers}$$

Example: graphene



reciprocal lattice



Planewave in 2D or 3D

$$\exp(i\mathbf{G} \cdot \mathbf{r})$$

Kohn-Sham wavefunction in a basis of planewaves

$$\phi_i(\mathbf{r}) = \sum_{\mathbf{G}} c_i(\mathbf{G}) \exp(i\mathbf{G} \cdot \mathbf{r})$$

By replacing in the KS equations we obtain

$$\frac{|\mathbf{G}|^2}{2} c_i(\mathbf{G}) + \sum_{\mathbf{G}'} V_{\text{tot}}(\mathbf{G} - \mathbf{G}') c_i(\mathbf{G}') = \varepsilon_i c_i(\mathbf{G})$$

How many planewave \mathbf{G} -vectors should we include in the expansion?



$$|\mathbf{G}| = 2\pi/a$$



$$|\mathbf{G}| = 2 \cdot 2\pi/a$$

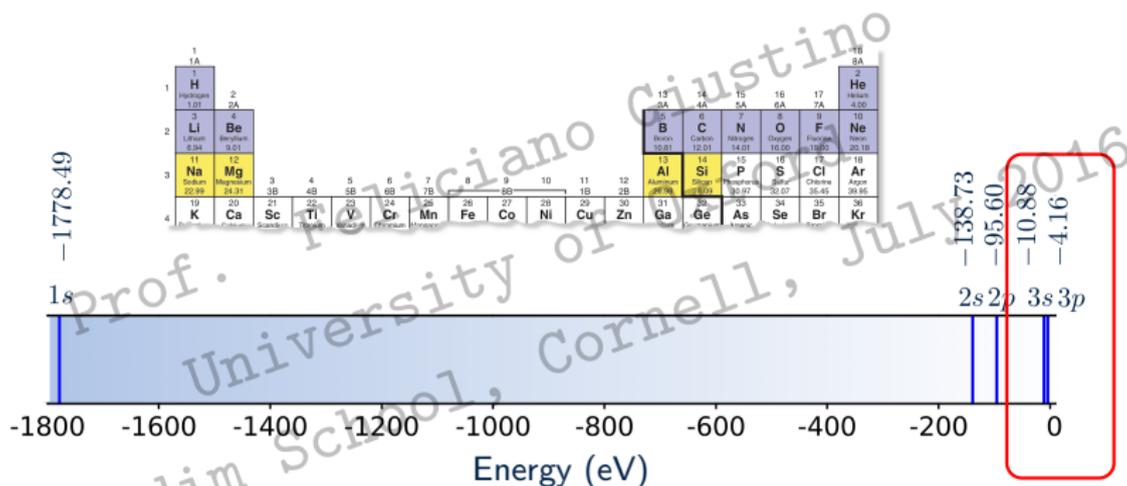


$$|\mathbf{G}| = 3 \cdot 2\pi/a$$

$$E_{\text{cut}} = \frac{|\mathbf{G}_{\text{max}}|^2}{2}$$

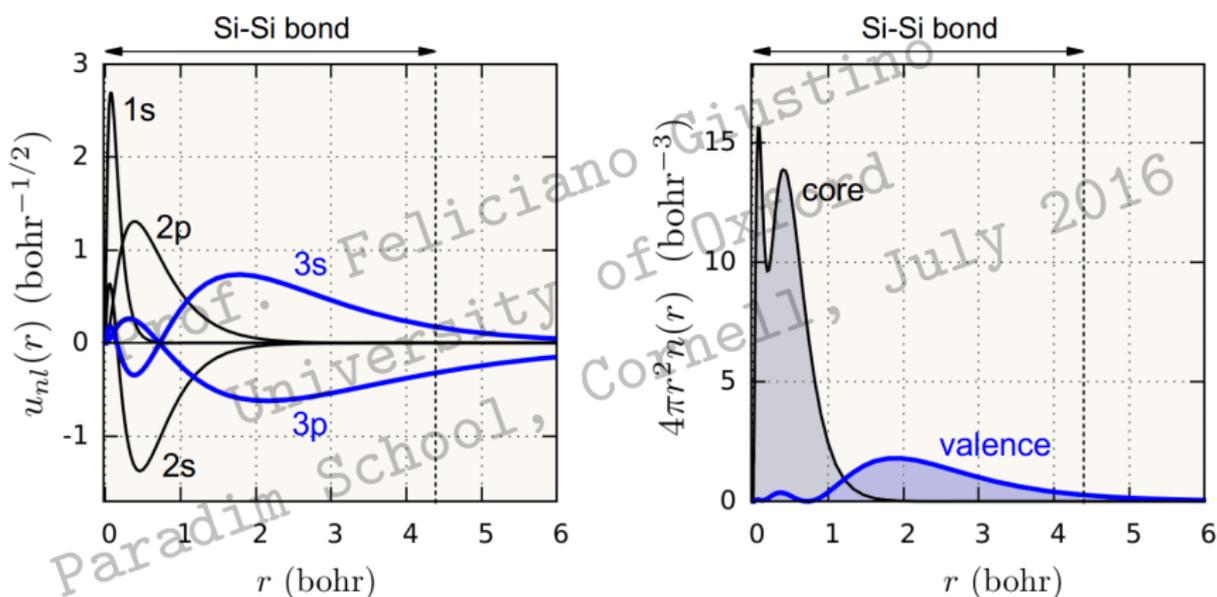
planewaves kinetic energy cutoff

Atomic levels of silicon (DFT/LDA)



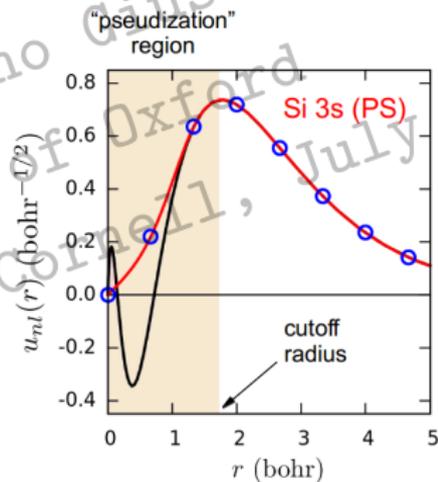
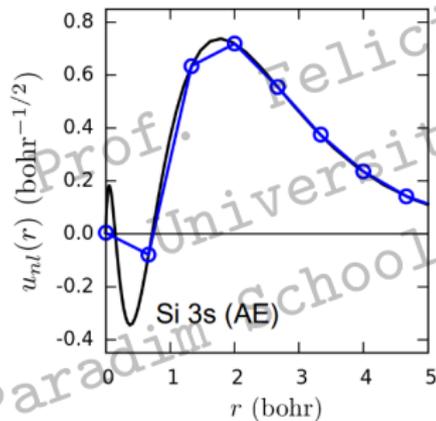
Only valence electrons
are important for
bonding and structure

Atomic wavefunctions of silicon (DFT/LDA)



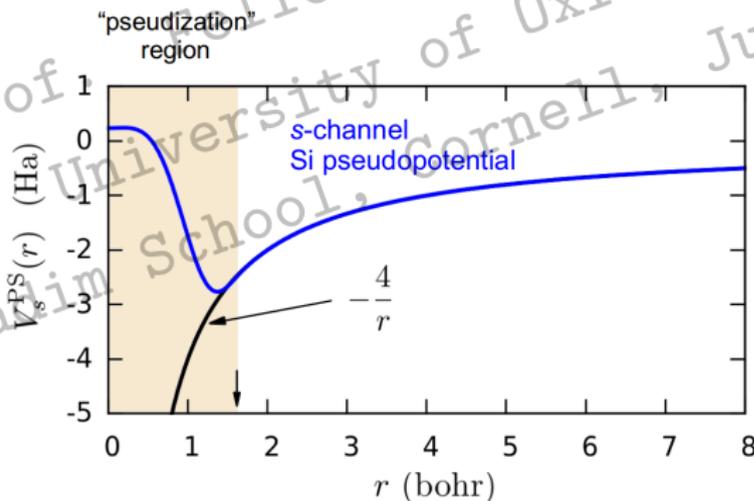
$$\psi_{nl}(\mathbf{r}) = \frac{u_{nl}(r)}{r} Y_{lm} \left(\frac{\mathbf{r}}{r} \right)$$

Contain planewaves cutoff by removing nodes \longrightarrow pseudization



Reverse-engineer the **pseudo-potential** potential which gives the **pseudo-wavefunction** as solution of the atomic Schrödinger equation

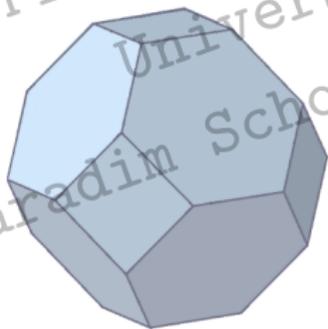
$$-\frac{1}{2} \frac{d^2}{dr^2} u_{3s}^{\text{PS}} + V_{3s}^{\text{PS}} u_{3s}^{\text{PS}} = E_{3s} u_{3s}^{\text{PS}} \quad \rightarrow \quad V_{3s}^{\text{PS}} = E_{3s} + \frac{1}{2u_{3s}^{\text{PS}}} \frac{d^2 u_{3s}^{\text{PS}}}{dr^2}$$



In **crystalline** solids we label electronic states by their Bloch wavevector \mathbf{k}
[see books by Kittel or Ashcroft & Mermin]

Bloch theorem $\phi_{i\mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k}\cdot\mathbf{r}} u_{i\mathbf{k}}(\mathbf{r})$ with $u_{i\mathbf{k}}(\mathbf{r} + \mathbf{R}) = u_{i\mathbf{k}}(\mathbf{r})$

$$n(\mathbf{r}) = \sum_{i \in \text{occ}} |\phi_i(\mathbf{r})|^2 \longrightarrow \sum_{i \in \text{occ}} \int_{\text{BZ}} \frac{d\mathbf{k}}{\Omega_{\text{BZ}}} |u_{i\mathbf{k}}(\mathbf{r})|^2 \simeq \frac{1}{N_{\mathbf{k}}} \sum_{\mathbf{k} \in \text{BZ}} \sum_{i \in \text{occ}} |u_{i\mathbf{k}}(\mathbf{r})|^2$$



Brillouin zone of *fcc* crystal (eg silicon)

DFT codes use a uniform discretization of this volume, and reduce the number of \mathbf{k} -vectors using the crystal symmetry operations



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Lecture 3.1

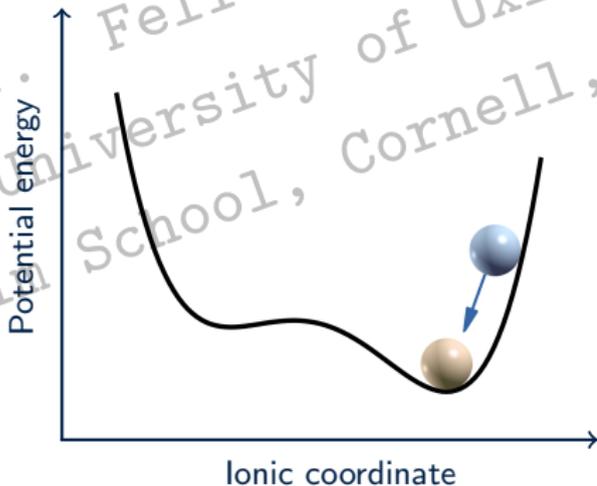
Equilibrium structures

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In order to find the equilibrium structures of materials

- 1) We determine the **potential energy surface** of the ions
- 2) We look for the minima of this surface \longrightarrow zero net forces on the ions



~~Clamped nuclei approximation~~

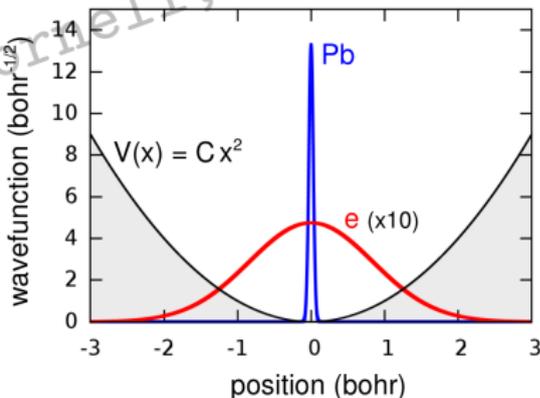
Back to the complete many-body Schrödinger equation for electrons & nuclei

$$\left[-\sum_i \frac{\nabla_i^2}{2} - \sum_I \frac{\nabla_I^2}{2M_I} - \sum_{i,I} \frac{Z_I}{|\mathbf{r}_i - \mathbf{R}_I|} + \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} + \frac{1}{2} \sum_{I \neq J} \frac{Z_I Z_J}{|\mathbf{R}_I - \mathbf{R}_J|} \right] \Psi = E_{\text{tot}} \Psi$$

Here $\Psi = \Psi(\mathbf{r}_1, \dots, \mathbf{r}_N, \mathbf{R}_1, \dots, \mathbf{R}_M)$

Example: the wavefunction of an electron vs the wavefunction of the Pb nucleus

$$\frac{1}{2M} \frac{d^2 \psi(x)}{dx^2} + Cx^2 \psi(x) = E \psi(x)$$



Born and Oppenheimer (1927) proposed the following approximation

- Factorize the electron-nuclear wavefunction

$$\Psi(\mathbf{r}_1, \dots, \mathbf{r}_N, \mathbf{R}_1, \dots, \mathbf{R}_M) \simeq \Psi_{\mathbf{R}}(\mathbf{r}_1, \dots, \mathbf{r}_N) \chi(\mathbf{R}_1, \dots, \mathbf{R}_M)$$

- Find the electronic part as the ground state of Schrödinger equation with the nuclei clamped at $\mathbf{R}_1, \dots, \mathbf{R}_M$

$$\left[-\sum_i \frac{\nabla_i^2}{2} + \sum_i V_n(\mathbf{r}_i; \mathbf{R}) + \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} \right] \Psi_{\mathbf{R}} = E(\mathbf{R}_1, \dots, \mathbf{R}_M) \Psi_{\mathbf{R}}$$

- Replace the result in the complete MBSE of the previous slide

$$\left[-\sum_I \frac{\nabla_I^2}{2M_I} + \frac{1}{2} \sum_{I \neq J} \frac{Z_I Z_J}{|\mathbf{R}_I - \mathbf{R}_J|} + E(\mathbf{R}_1, \dots, \mathbf{R}_M) \right] \chi = E_{\text{tot}} \chi$$

Schrödinger equation for nuclei

$$\underbrace{-\sum_I \frac{\nabla_I^2}{2M_I}}_{\text{Kinetic Energy}} \chi + \underbrace{\left[\frac{1}{2} \sum_{I \neq J} \frac{Z_I Z_J}{|\mathbf{R}_I - \mathbf{R}_J|} + E(\mathbf{R}_1, \dots, \mathbf{R}_M) \right]}_{\text{Potential Energy}} \chi = E_{\text{tot}} \chi$$

Potential energy surface

$$U(\mathbf{R}_1, \dots, \mathbf{R}_M) = \frac{1}{2} \sum_{I \neq J} \frac{Z_I Z_J}{|\mathbf{R}_I - \mathbf{R}_J|} + E(\mathbf{R}_1, \dots, \mathbf{R}_M)$$

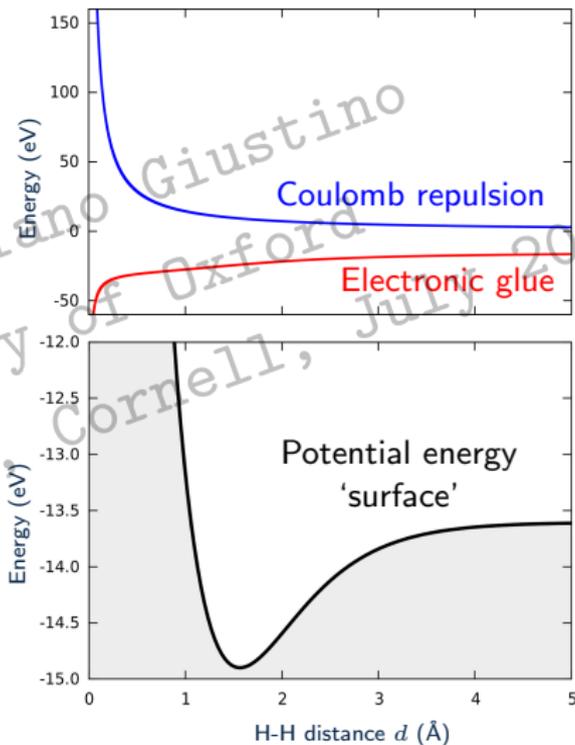
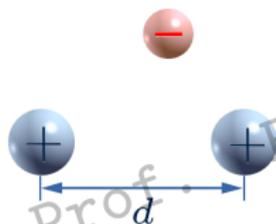
↑
Coulomb repulsion
between positive nuclei

↑
Glue resulting from the
negative charge of the electrons
(we get this from **DFT**)

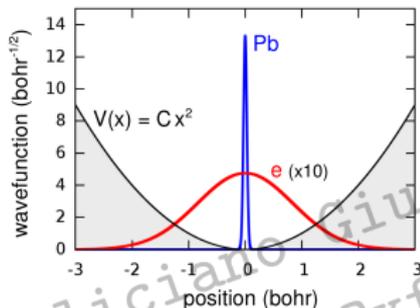
Potential energy surface

H_2^+ molecular ion

Example from Exercise 4.4 of the book



From slide #4



$$-\sum_I \frac{\nabla_I^2}{2M_I} + U(\mathbf{R}_1, \dots, \mathbf{R}_M) \xrightarrow{\text{classical nuclei}} \sum_I \frac{\mathbf{P}_I^2}{2M_I} + U(\mathbf{R}_1, \dots, \mathbf{R}_M)$$

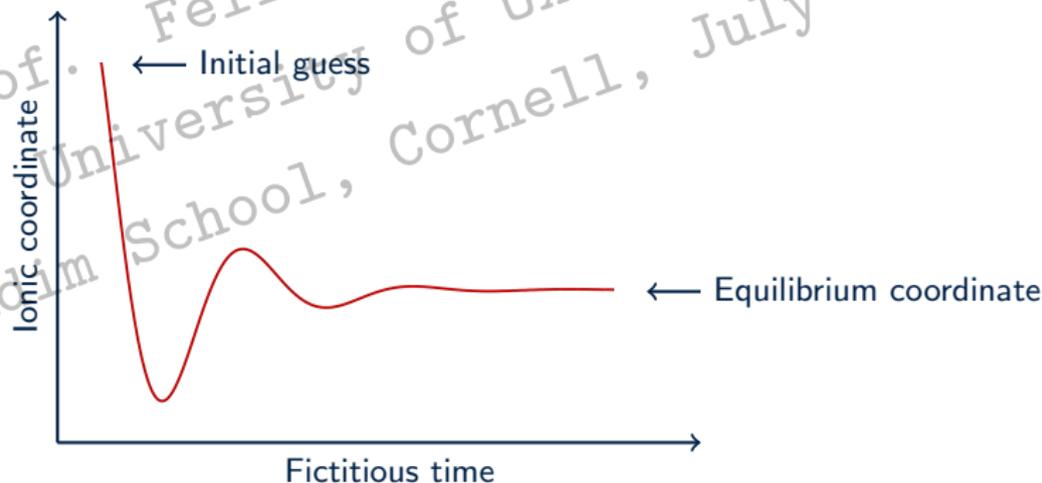
$$M_I \frac{d^2 \mathbf{R}_I}{dt^2} = \mathbf{F}_I = -\frac{\partial U}{\partial \mathbf{R}_I}$$

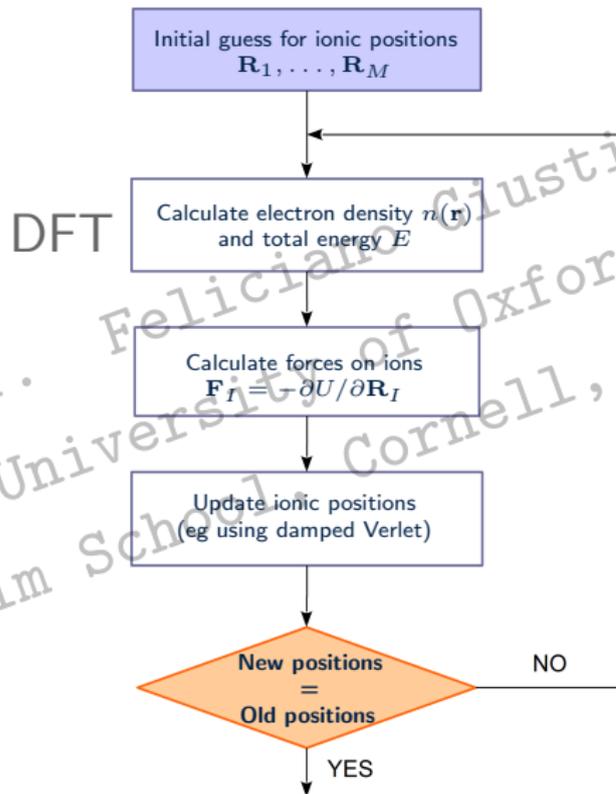
Newton's equation for nuclei

Finding the minima of the PES using damped molecular dynamics

$$M \frac{d^2x}{dt^2} = -\frac{\partial U}{\partial x} - \underbrace{\frac{2M}{\tau} \frac{dx}{dt}}_{\text{Friction term}}$$

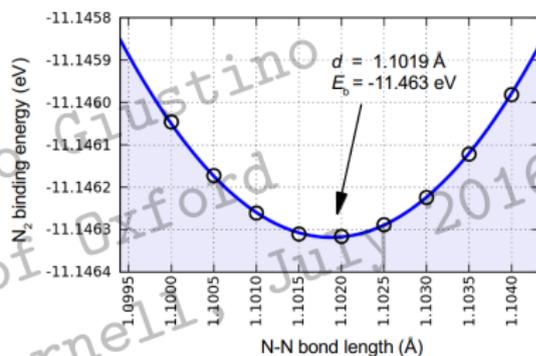
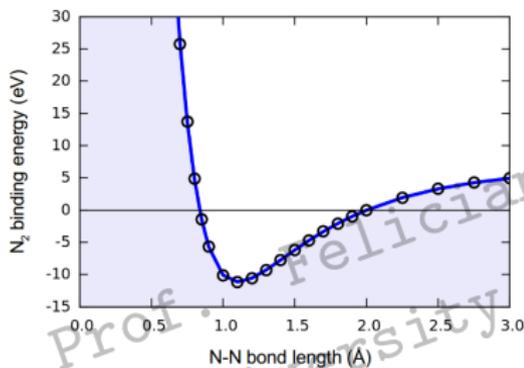
(Verlet)
$$M \frac{x_{i+1} - 2x_i + x_{i-1}}{\Delta t^2} = -\frac{U(x_i) - U(x_{i-1})}{x_i - x_{i-1}} - \frac{2M}{\tau} \frac{x_{i+1} - x_{i-1}}{2\Delta t}$$





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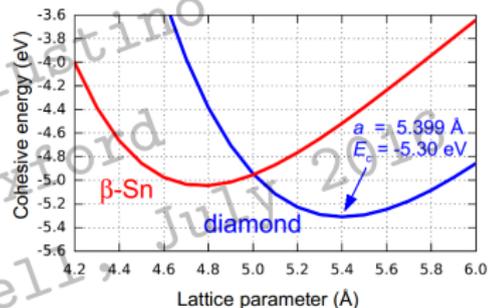
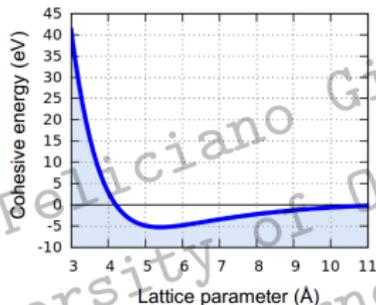
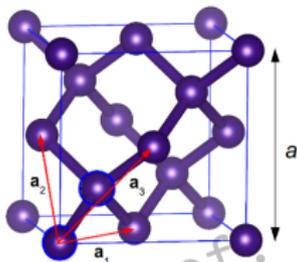
Simplest case of structural optimization: N_2 diatomic molecule



	DFT/LDA	Experiment	Rel. Error
bond length (Å)	1.102	1.098	0.4%
binding energy (eV)	11.46	9.76	17%

Note Nitrogen is $[1s^2]2s^2p^3$, therefore it has a spin $S = 3/2$ after the first Hund's rule. These calculations are spin-unpolarized (N_2 has 14 electrons), therefore the result at large separation is higher than twice the energy of one N atom

Structural optimization of bulk crystals: Silicon



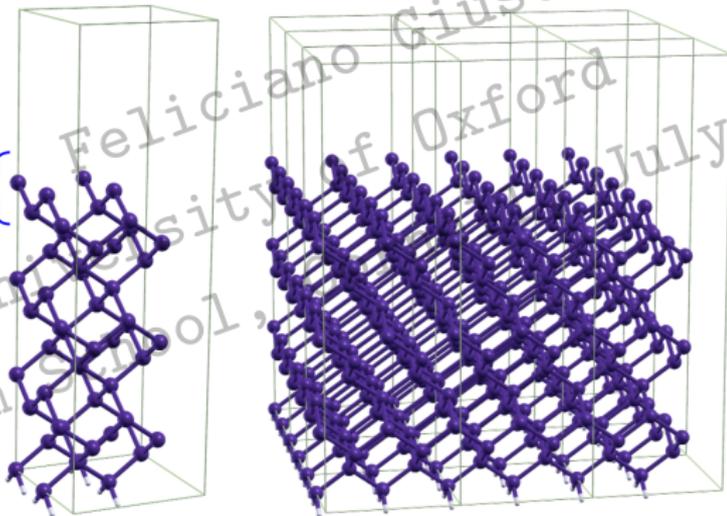
	DFT/LDA	Experiment	Rel. Error
lattice parameter (Å)	5.40	5.43	0.6%
cohesive energy (eV)	5.30	4.62	15%

Structural optimization of surfaces: Clean Si(001) surface

unit cell

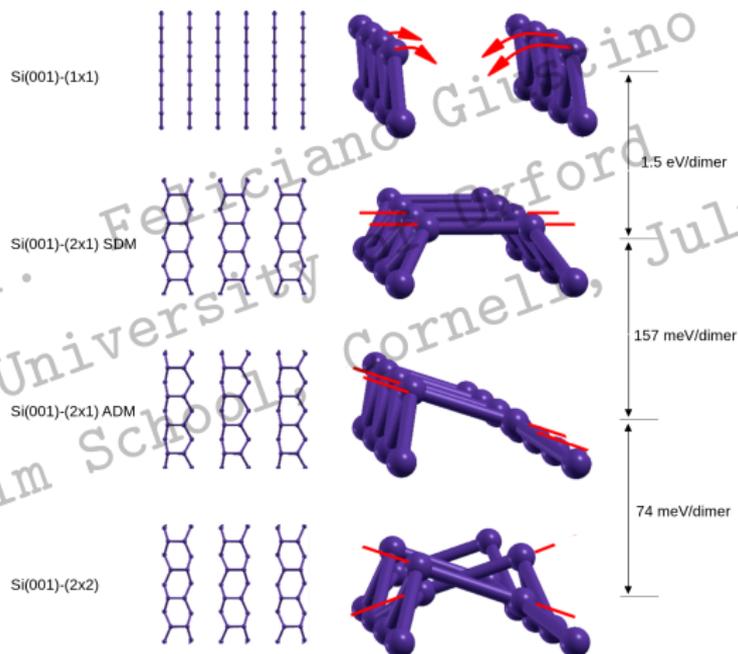
periodic replicas

surface atoms



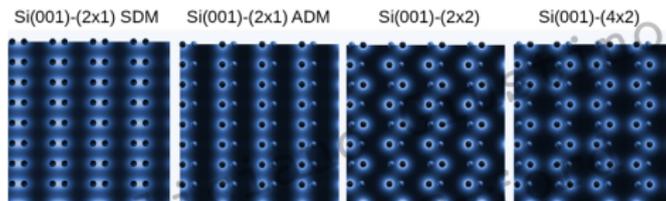
52 Si atoms | 13 layers | 8 H atoms for passivation | 4 layers kept fixed

Structural optimization of surfaces: Clean Si(001) surface

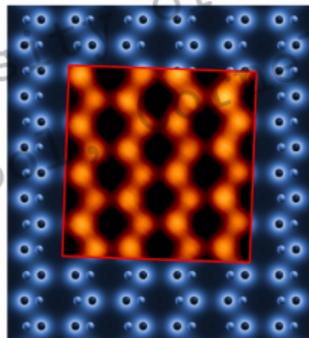


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July 2016

Comparison between calculated and measured STM images



Si(001)-(4x2): DFT vs. experiment



Experimental STM image courtesy of T. Yokoyama
<http://dx.doi.org/10.1103/PhysRevB.61.R5078>



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Paradim School, Cornell, July 2016

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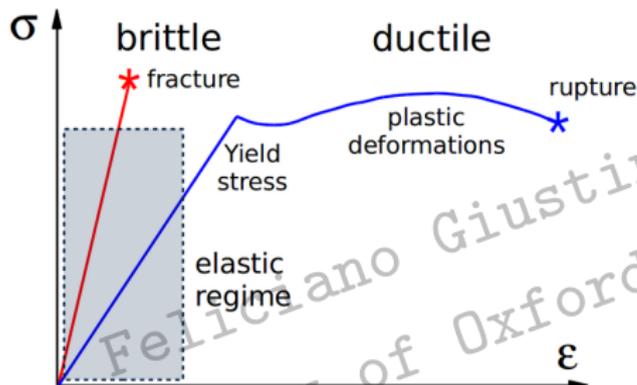


Lecture 3.2

Elastic properties

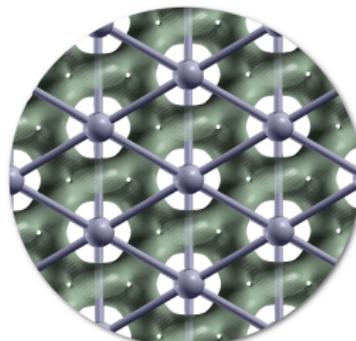
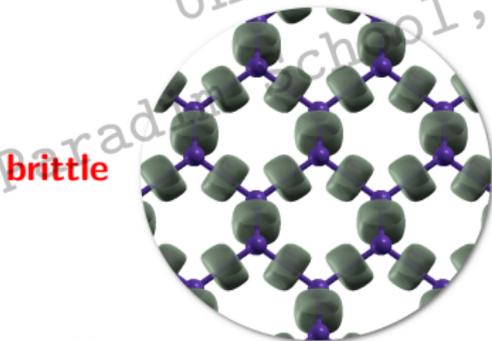
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silicon (diamond structure)

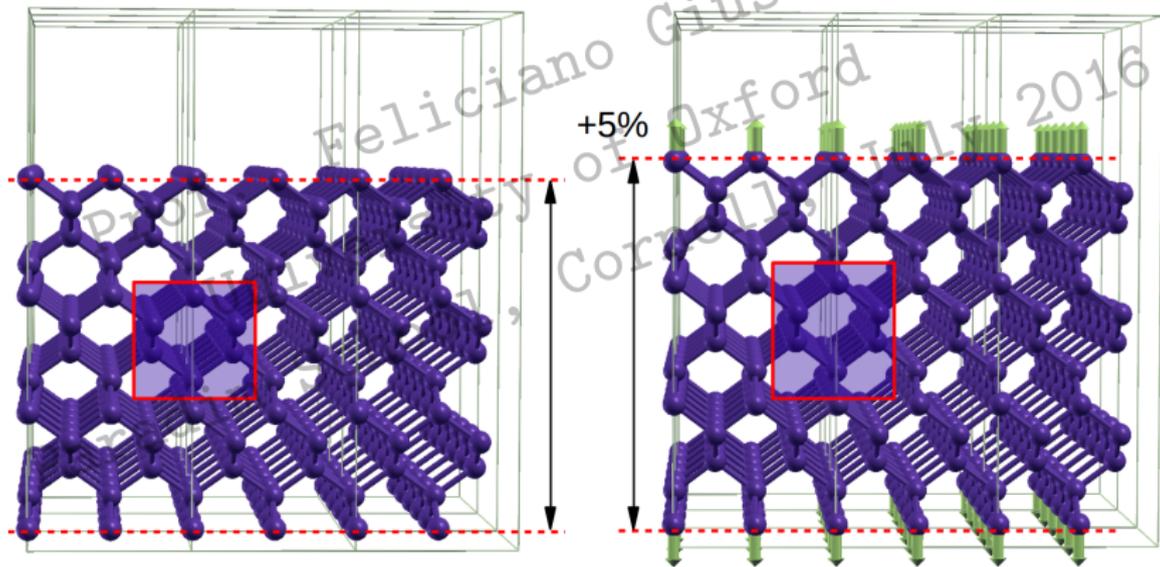
bcc tungsten

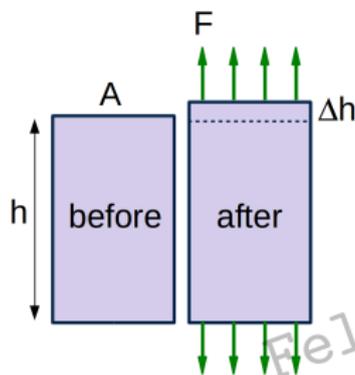


Notion of stress and strain: a **computer experiment** on silicon

Equilibrium structure

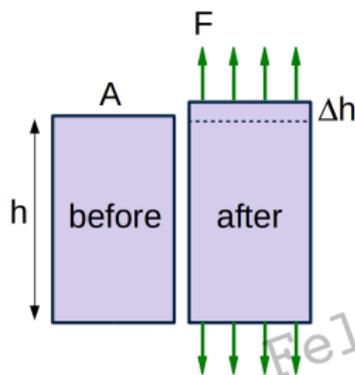
Stretched slab





$$\sigma = \frac{F_{\text{tot}}}{A} \quad \epsilon = \frac{\Delta h}{h} \quad \sigma = Y\epsilon$$

transverse size	7.635 Å
no. of surface atoms	4
force per atom	0.682 eV/Å
σ	7.5 GPa
ϵ	5%
Y	150 GPa
experiment	166 GPa
deviation	11%



Work-energy theorem

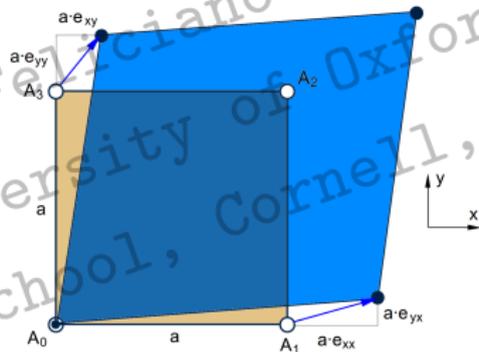
The work of external forces on a system equals the increase of its total potential and kinetic energies

$$\Delta U = \int_h^{h+\Delta h} F(z) dz = Ah \int_h^{h+\Delta h} \frac{F(z)}{A} \frac{dz}{h} = \Omega \int_0^\epsilon \sigma d\epsilon = \Omega \int_0^\epsilon C \epsilon d\epsilon = \frac{1}{2} \Omega C \epsilon^2$$

$$\frac{1}{\Omega} \frac{\partial U}{\partial \epsilon} = C \epsilon = \sigma \qquad \frac{1}{\Omega} \frac{\partial^2 U}{\partial \epsilon^2} = C$$

General transformation of the atomic coordinates: the **strain tensor**

$$R'_{I\alpha} = \sum_{\beta} (\delta_{\alpha\beta} + e_{\alpha\beta}) R_{I\beta}$$



$$\sigma_{\alpha\beta} = \frac{1}{\Omega} \frac{\partial U}{\partial \epsilon_{\alpha\beta}} \quad \frac{\Delta U}{\Omega} = \frac{1}{2} \epsilon_{\alpha\beta} \epsilon_{\gamma\delta}$$

Voigt notation

$$\epsilon_{\alpha\beta} = \begin{pmatrix} \epsilon_{xx} & \epsilon_{xy} & \epsilon_{xz} \\ \epsilon_{xy} & \epsilon_{yy} & \epsilon_{yz} \\ \epsilon_{xz} & \epsilon_{yz} & \epsilon_{zz} \end{pmatrix} \longrightarrow \epsilon_i = \begin{pmatrix} \epsilon_1 & \epsilon_6 & \epsilon_5 \\ & \epsilon_2 & \epsilon_4 \\ & & \epsilon_3 \end{pmatrix}$$

Engineering strain

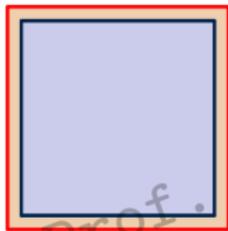
$$\frac{\Delta U}{\Omega} = \frac{1}{2} C_{ij} u_i u_j \quad \text{with} \quad u_i = \begin{cases} \epsilon_i & \text{if } i = 1, 2, 3 \\ 2\epsilon_i & \text{if } i = 4, 5, 6 \end{cases}$$

$6^2 = 36$ constants
 (21 independent)

Example: Cubic system

$$C_{ij} = \begin{pmatrix} C_{11} & C_{12} & C_{12} & 0 & 0 & 0 \\ C_{12} & C_{11} & C_{12} & 0 & 0 & 0 \\ C_{12} & C_{12} & C_{11} & 0 & 0 & 0 \\ 0 & 0 & 0 & C_{44} & 0 & 0 \\ 0 & 0 & 0 & 0 & C_{44} & 0 \\ 0 & 0 & 0 & 0 & 0 & C_{44} \end{pmatrix}$$

Isotropic deformation

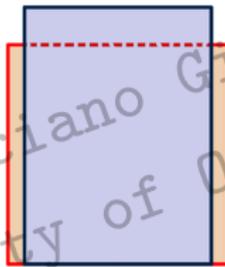


$$u_1 = u_2 = u_3 = \eta$$

$$u_4 = u_5 = u_6 = 0$$

$$\frac{\Delta U}{\Omega} = \frac{3}{2}(C_{11} + 2C_{12})\eta^2$$

Tetragonal deformation



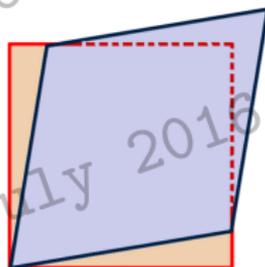
$$u_1 = u_2 = -\eta$$

$$u_3 = 2\eta$$

$$u_4 = u_5 = u_6 = 0$$

$$\frac{\Delta U}{\Omega} = 3(C_{11} - C_{12})\eta^2$$

Trigonal deformation



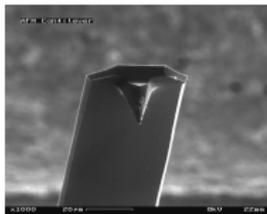
$$u_1 = u_2 = u_3 = 0$$

$$u_4 = u_5 = 0$$

$$u_6 = \eta$$

$$\frac{\Delta U}{\Omega} = \frac{1}{2}C_{44}\eta^2$$

Elastic constants of **silicon** in GPa



en.wikipedia.org/wiki/Cantilever

	DFT/LDA	Experiment	Rel. Error
C_{11}	161	165.6	3%
C_{12}	62	63.9	3%
C_{44}	78	79.5	2%



en.wikipedia.org/wiki/Tungsten

Bulk modulus of **tungsten** in GPa

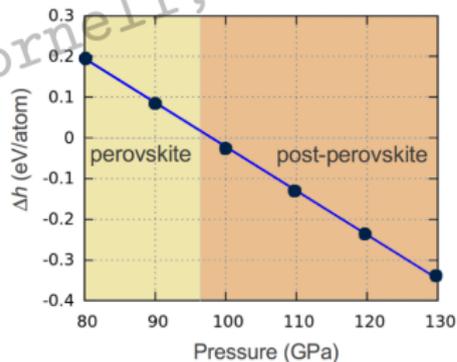
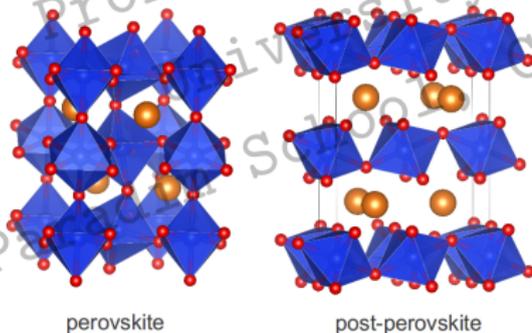
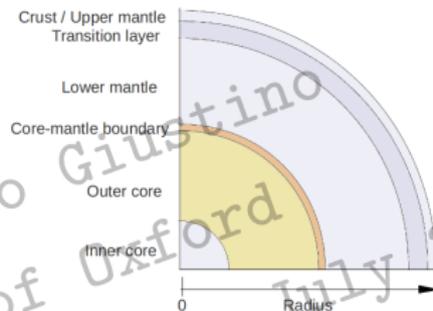
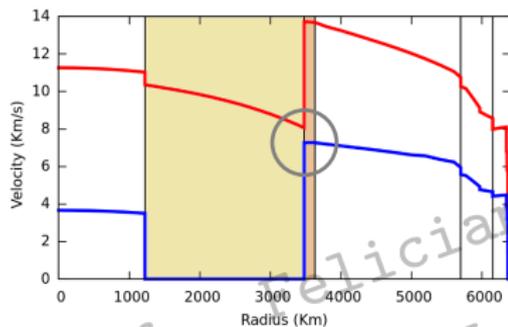
$$B = \Omega \frac{\partial^2 U}{\partial \Omega^2} = \frac{1}{3}(C_{11} + 2C_{12})$$

	DFT/LDA	Experiment	Rel. Error
B	328	314	4%

- The stress tensor can also be calculated in DFT w/o considering explicit distortions (stress theorem)
Nielsen and Martin, Phys. Rev. Lett. 50, 697 (1983)
- It is possible to perform DFT calculations for an arbitrary external load → common to study pressure-dependence
Parrinello and Rahman, J. Appl. Phys. 52, 7182 (1981)

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July 2016

Example: Post-perovskite MgSiO_3



litaka et al, Nature 430, 442 (2004)



An introduction to density functional theory for experimentalists

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Paradim School, Cornell, July 2016

Feliciano Giustino

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Lecture 4.1

Phonons in DFT

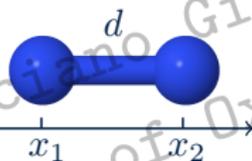
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From Lecture 3.1 (slide 8): Newton's equation for classical ions

$$M_I \frac{d^2 \mathbf{R}_I}{dt^2} = - \frac{\partial U}{\partial \mathbf{R}_I} \quad \leftarrow \text{Potential energy surface from DFT}$$

N₂ molecule



$$M_N \frac{d^2 x_1}{dt^2} = - \frac{\partial U}{\partial x_1}$$

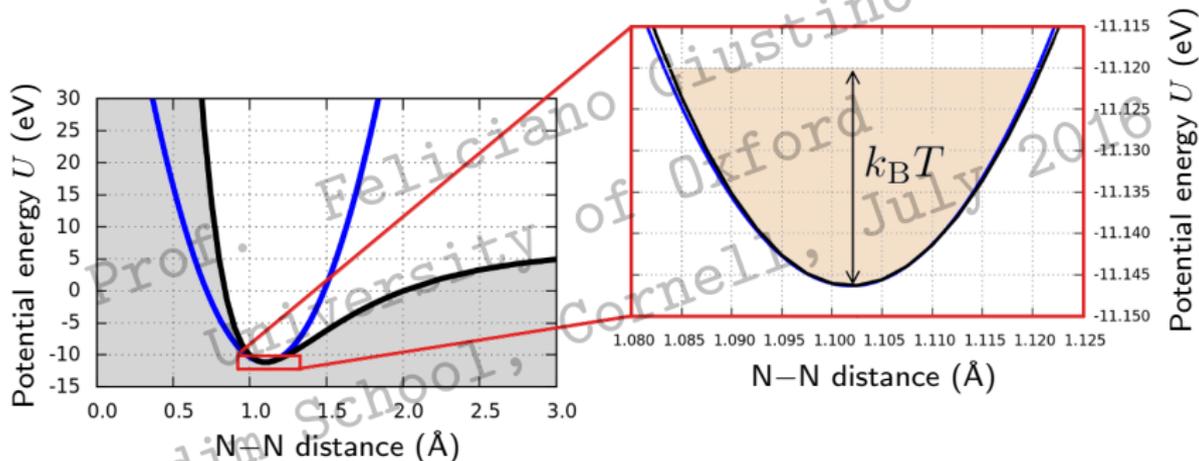
$$M_N \frac{d^2 x_2}{dt^2} = - \frac{\partial U}{\partial x_2}$$

mathematical detail

$$\begin{aligned} \frac{\partial U}{\partial x_1} &= \frac{\partial U}{\partial \bar{x}} \frac{\partial \bar{x}}{\partial x_1} - \frac{\partial U}{\partial d} \frac{\partial d}{\partial x_1} \\ &= \frac{1}{2} \frac{\partial U}{\partial \bar{x}} - \frac{\partial U}{\partial d} \end{aligned}$$

$$M_N \ddot{d} = M_N \frac{d^2}{dt^2} (x_2 - x_1) = - \left(\frac{\partial U}{\partial x_2} - \frac{\partial U}{\partial x_1} \right) = -2 \frac{\partial U}{\partial d}$$

$$\frac{M_N}{2} \ddot{d} = -\frac{\partial U}{\partial d}$$



$$U(d) = U_0 + \frac{1}{2} K(d-d_0)^2 \longrightarrow \frac{\partial U}{\partial d} = K(d-d_0)$$

Harmonic approximation (Hooke's law)

Stretching frequency of N₂

$$\ddot{d} = -\frac{2K}{M_N}(d - d_0)$$

$$\omega_{N_2} = \sqrt{\frac{2K}{M_N}}$$

	DFT/LDA	experiment	deviation
$\hbar\omega_{N_2}$ (meV)	288.9	300.4	4%
	harmonic	anharmonic	deviation
$\hbar\omega_{N_2}$ (meV)	288.9	304.2	5%

[Exercise 8.1 of Book]



Taylor expansion of potential energy surface for small displacements

$$U = U_0 + \sum_{I\alpha} u_{I\alpha} \frac{\partial U}{\partial R_{I\alpha}} + \frac{1}{2} \sum_{I\alpha, J\beta} \frac{\partial^2 U}{\partial R_{I\alpha} \partial R_{J\beta}} u_{I\alpha} u_{J\beta} + \mathcal{O}(u^3)$$

$$K_{I\alpha, J\beta}$$

matrix of force constants

Equation of motion in the harmonic approximation

$$M_I \ddot{u}_{I\alpha} = - \sum_{J\beta} K_{I\alpha, J\beta} u_{J\beta}$$

Try with $u_{I\alpha}(t) = u_{I\alpha}^0 \exp(i\omega t)$ and rearrange

$$\sum_{J\beta} K_{I\alpha, J\beta} u_{J\beta}^0 = M_I \omega^2 u_{I\alpha}^0$$

Get rid of masses

$$\sum_{J\beta} \frac{K_{I\alpha, J\beta}}{\sqrt{M_I M_J}} \sqrt{M_J} u_{J\beta}^0 = \omega^2 \sqrt{M_I} u_{I\alpha}^0$$

dynamical matrix

mass-scaled eigenmode

Dynamical matrix

$$D_{I\alpha, J\beta} = \frac{1}{\sqrt{M_I M_J}} \left. \frac{\partial^2 U}{\partial R_{I\alpha} \partial R_{J\beta}} \right|_{\text{Eq.}}$$

D

e

$= \omega^2$

e

$3M \times 3M$
(M atoms)

Standard matrix eigenvalue problem

Frozen-phonon method

$$\frac{\partial^2 U}{\partial R_{I\alpha}^2} \simeq \frac{U(R_{I\alpha}^0 + \mathbf{u}) - 2U_0 + U(R_{I\alpha}^0 - \mathbf{u})}{u^2}$$

or alternatively using the forces

$$\frac{\partial^2 U}{\partial R_{I\alpha}^2} \simeq \frac{F_{I\alpha}(R_{I\alpha}^0 + \mathbf{u}) - F_{I\alpha}(R_{I\alpha}^0 - \mathbf{u})}{2u}$$

Density-functional perturbation theory (DFPT)

The method of choice for crystals

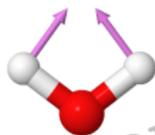
[Baroni et al, Rev. Mod. Phys. 73, 515 (2001)]

Example: water molecule

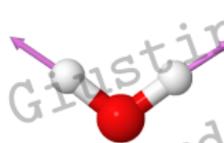
$$\hbar^2 \mathbf{D} = \begin{pmatrix} 82 & 82 & -0 & -164 & -164 & -176 & -164 & -164 & 176 \\ & 82 & -0 & -164 & -164 & -176 & -164 & -164 & 176 \\ & & 103 & -136 & -136 & -206 & 136 & 136 & -206 \\ & & & 710 & 711 & 625 & -55 & -55 & -81 \\ & & & & 710 & 625 & -55 & -55 & -81 \\ & & & & & 791 & 81 & 81 & 31 \\ & & & & & & 710 & 711 & -625 \\ & & & & & & & 710 & -625 \\ & & & & & & & & 791 \end{pmatrix} 100 \text{ meV}^2$$

- 9 eigenvalues
- 3 rigid-body translations
 - 2 rigid-body librations
 - 1 rigid-body spinning
 - 3 internal vibrations

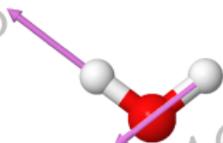
Example: water molecule



bending



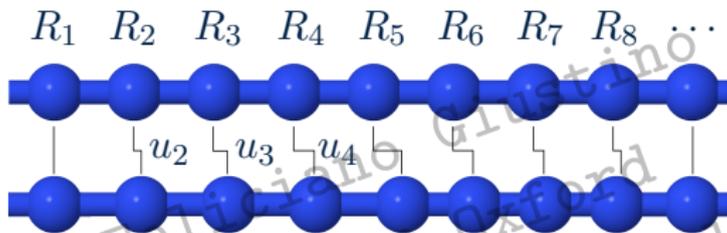
symmetric
stretching



asymmetric
stretching

DFT frequency (meV)	189	453	466
Expt. frequency (meV)	198	458	473
deviation	4.8%	1.1%	1.5%

Simplest model: 1D chain of atoms moving along 1 direction



$$M\ddot{u}_I = - \sum_J K_{IJ} u_J$$

Sound waves $\frac{1}{v_s^2} \frac{\partial^2 p}{\partial t^2} = \frac{\partial^2 p}{\partial x^2} \longrightarrow p(x, t) = p_0 e^{i(qx - \omega t)}$

By analogy we can try $u_I(t) = u_0 e^{i(qR_I - \omega t)}$

$$M \omega^2 e^{iqR_I} = \sum_J K_{IJ} e^{iqR_J}$$

$$\omega^2 = \frac{1}{M} \sum_J K_{IJ} e^{iq(R_J - R_I)}$$

In crystals the force constants are **translationally invariant**, ie $K_{IJ} = K_{I+N, J+N}$

$$\omega^2(q) = \frac{1}{M} \sum_J K_{0J} e^{iqR_J}$$

The eigenfrequencies are obtained as the **Fourier transform** of the force constants

Dynamical matrix for 2D/3D crystals

$$D_{I\alpha, J\beta}(\mathbf{q}) = \frac{1}{\sqrt{M_I M_J}} \sum_{\mathbf{R}} e^{i\mathbf{q} \cdot \mathbf{R}} e^{i\mathbf{q} \cdot (\tau_J - \tau_I)} K_{0I\alpha, \mathbf{R}J\beta}$$

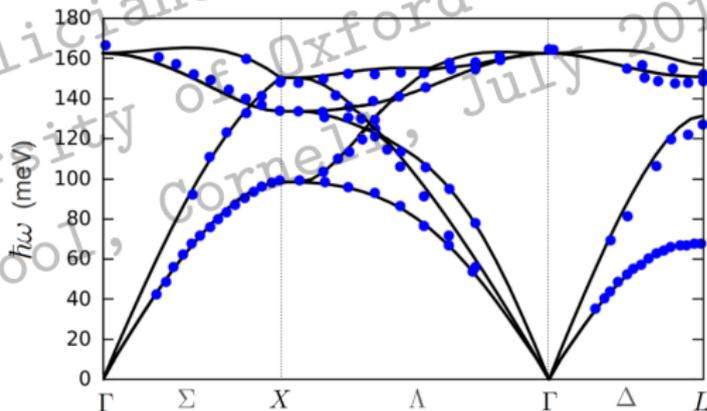
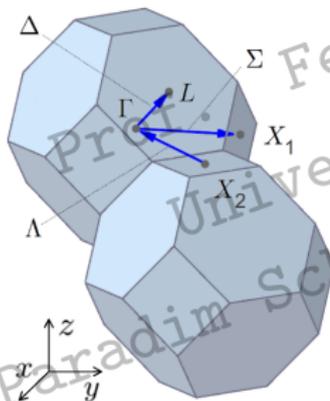
\mathbf{R} reciprocal lattice vector

τ_I position of atom I in the primitive unit cell

Example: diamond

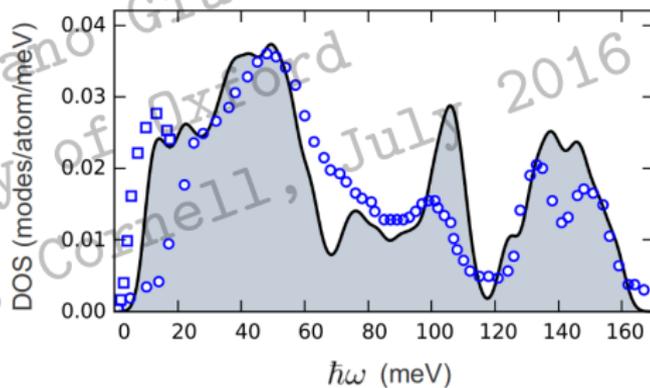
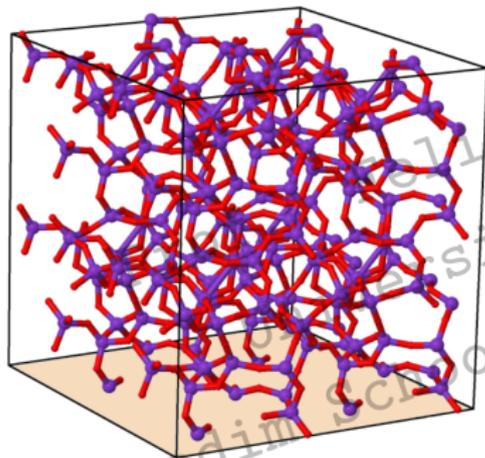


en.wikipedia.org/wiki/Oppenheimer_Diamond



- DFT/LDA calculation
- Inelastic neutron scattering

Example: a-SiO₂



- Inelastic neutron scattering
- DFT/LDA calculation



An introduction to density functional theory for experimentalists

Feliciano Giustino

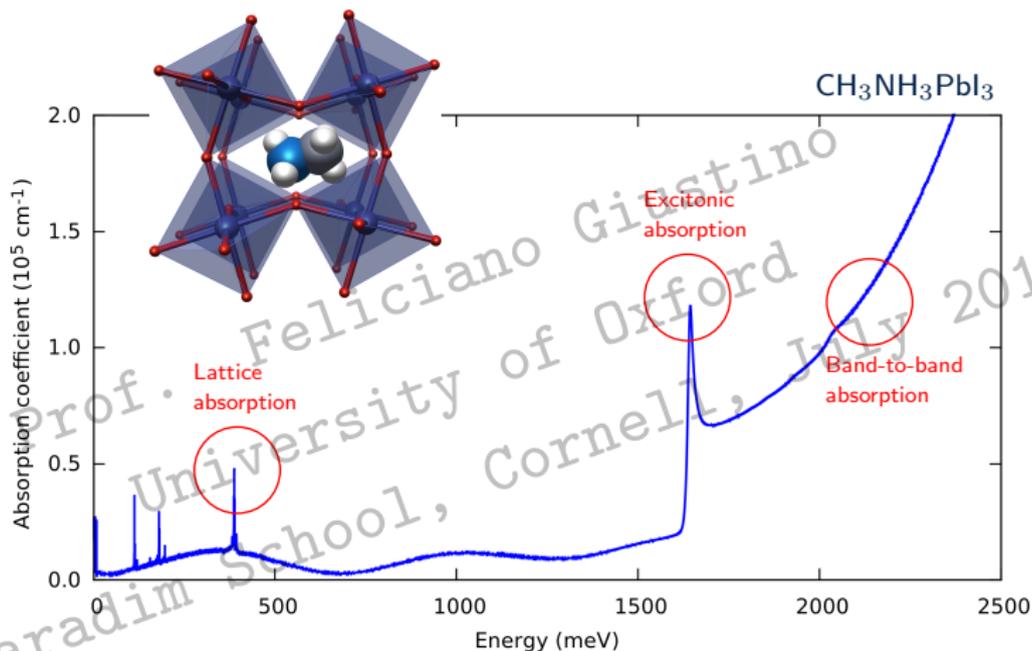
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Lecture 4.2

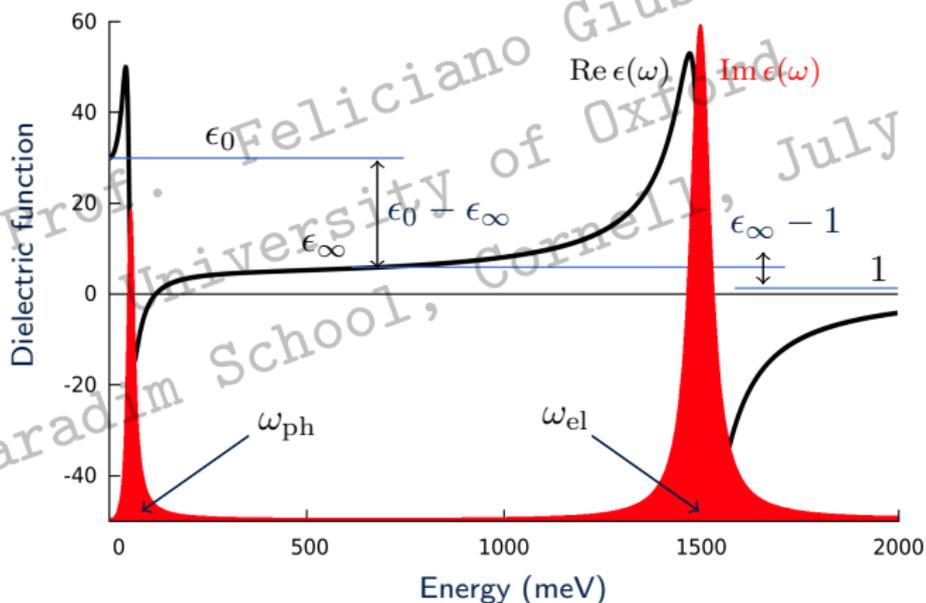
IR spectra & dielectric constants



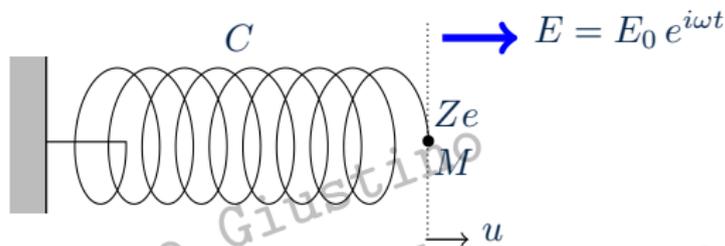
Experiment by R. Milot & M. Johnston
Perez et al, J. Phys. Chem. C 119, 25703 (2015)

General structure of the frequency-dependent dielectric function

$$\epsilon(\omega) = 1 + \frac{\epsilon_\infty - 1}{1 - (\omega/\omega_{el})^2} + \frac{\epsilon_0 - \epsilon_\infty}{1 - (\omega/\omega_{ph})^2}$$



Classical point charge
attached to spring



Equation of motion $M\ddot{u}(t) = -Cu(t) + ZeE(t)$

Set $u(t) = u_0 e^{i\omega t}$

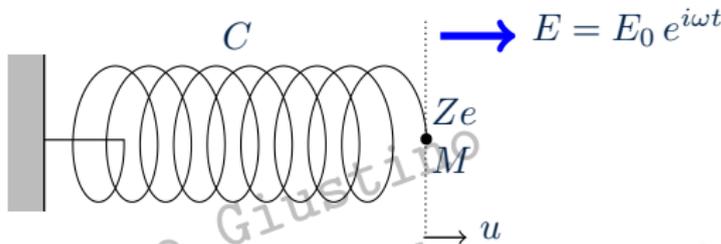
We obtain $-M\omega^2 u_0 = -Cu_0 + ZeE_0$

W/o electric field $-M\omega_0^2 u_0 = -Cu_0$

Difference $M(\omega_0^2 - \omega^2)u_0 = ZeE_0$

Induced displacement $u_0 = \frac{e}{M} \frac{Z}{\omega_0^2 - \omega^2} E_0$

Classical point charge
attached to spring



Induced displacement

$$u_0 = \frac{e}{M} \frac{Z}{\omega_0^2 - \omega^2} E_0$$

Macroscopic polarization

1 oscillator per unit cell of volume Ω

$$P(t) = \frac{1}{\Omega} Ze u(t) = P_0 e^{i\omega t} \rightarrow P_0 = \frac{1}{\Omega} Ze u_0$$

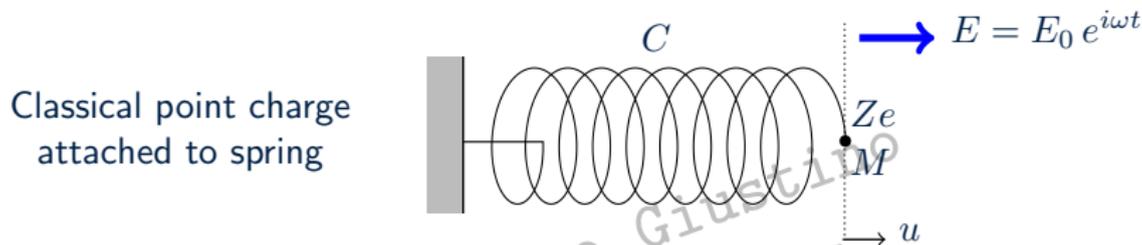
Dielectric function

$$P_0 + P_{el} = \epsilon_0 \epsilon_1(\omega) E_0, \quad P_{el} = \epsilon_0 \epsilon^\infty E_0$$

$$\epsilon_1(\omega) = \epsilon^\infty + \frac{e^2}{4\pi\epsilon_0} \frac{4\pi}{\Omega} \frac{1}{M} \frac{Z^2}{\omega_0^2 - \omega^2}$$

Born charge

$$Z = \frac{\Omega}{e} \frac{\partial P_0}{\partial u_0} \quad \text{or} \quad Z = \frac{1}{e} \frac{\partial F}{\partial E}$$



Dielectric function

$$\epsilon_1(\omega) = \epsilon^\infty + \frac{e^2}{4\pi\epsilon_0} \frac{4\pi}{\Omega} \frac{1}{M} \frac{Z^2}{\omega_0^2 - \omega^2}$$

Static dielectric constant

$$\epsilon_0 = \epsilon^\infty + \frac{e^2}{4\pi\epsilon_0} \frac{4\pi}{\Omega} \frac{1}{M} \frac{Z^2}{\omega_0^2}$$

IR intensity

[see Sec. 10.2.1 of Book]

$$I(\omega) \propto \omega \epsilon_2(\omega) \propto Z^2 \delta(\omega - \omega_0)$$

Low-frequency dielectric constant tensor ($\mathbf{q} \rightarrow 0$)

$$\epsilon_{1,\alpha\beta}(\omega) = \epsilon_{1,\alpha\beta}^{\infty} - \frac{e^2}{4\pi\epsilon_0} \frac{4\pi}{\Omega} \frac{1}{M_0} \sum_n \frac{Z_{\alpha n} Z_{\beta n}}{\omega_n^2 - \omega^2}$$

high-frequency
dielectric constant

phonon frequencies
at $\mathbf{q} = 0$

Low-frequency dielectric constant tensor ($\mathbf{q} \rightarrow 0$)

$$\epsilon_{1,\alpha\beta}(\omega) = \epsilon_{1\alpha\beta}^{\infty} + \frac{e^2}{4\pi\epsilon_0} \frac{4\pi}{\Omega} \frac{1}{M_0} \sum_n \frac{Z_{\alpha n} Z_{\beta n}}{\omega_n^2 - \omega^2}$$

Mode effective charge vector

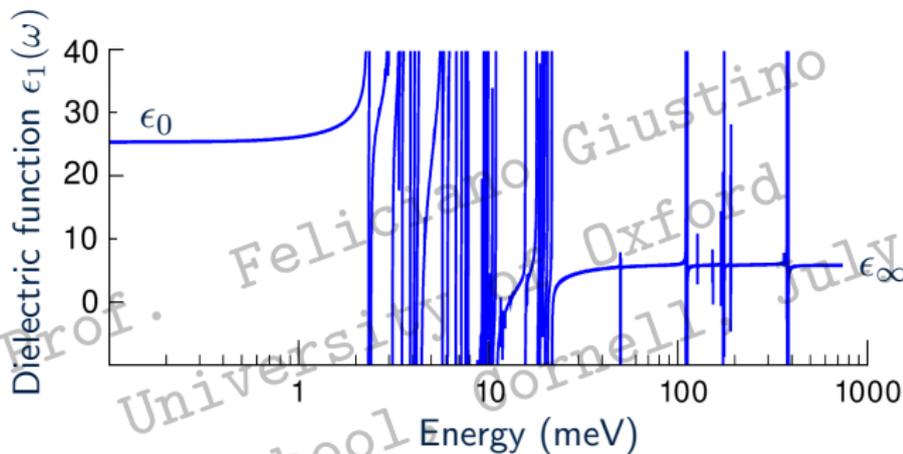
$$Z_{\alpha n} = \sum_{J\beta} Z_{J,\alpha\beta}^* \sqrt{\frac{M_0}{M_J}} e_{J\beta,n}$$

Born effective charge tensor

$$Z_{J,\alpha\beta}^* = \frac{\Omega}{e} \frac{\partial P_{\alpha}}{\partial R_{J\beta}}$$

Phonon eigenmodes at $\mathbf{q} = 0$

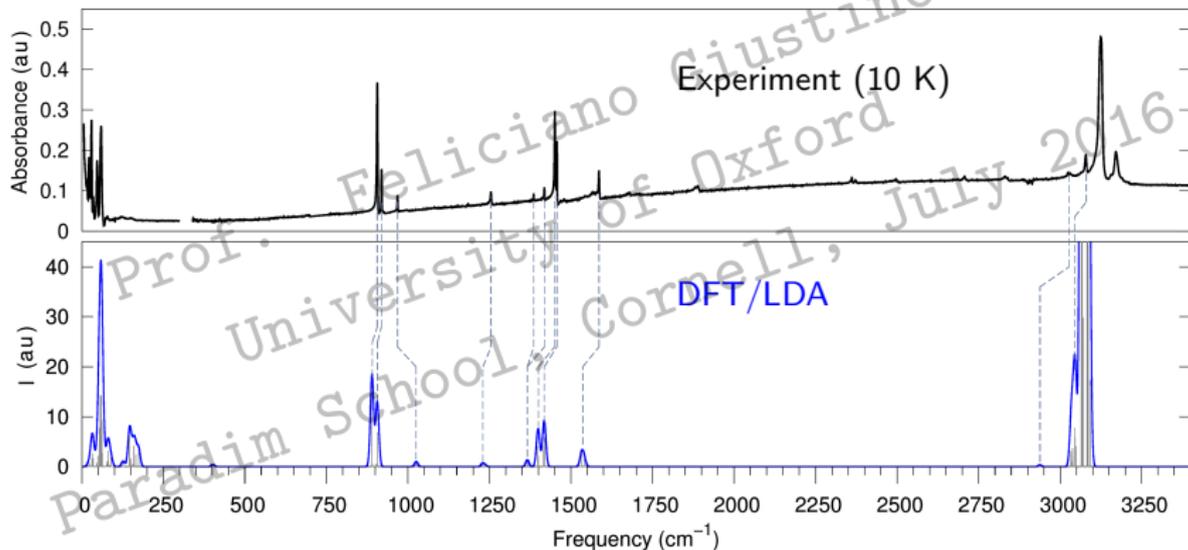
Example: Dielectric constant of $\text{CH}_3\text{NH}_3\text{PbI}_3$



	DFT/LDA	Experiment	deviation
ϵ_∞	5.9	6.5	10%
ϵ_0	25.3	30.5	20%

Perez et al, J. Phys. Chem. C 119, 25703 (2015)

Example: IR absorption of $\text{CH}_3\text{NH}_3\text{PbI}_3$



Perez et al, J. Phys. Chem. C 119, 25703 (2015)

$$Z_{I,\alpha\beta}^* = \begin{cases} \frac{\Omega}{e} \frac{\partial P_\alpha}{\partial R_{I\beta}} & \text{Change of electronic polarization upon} \\ & \text{atomic displacement} \\ \frac{1}{e} \frac{\partial F_{I\alpha}}{\partial E_\beta} & \text{Change of force on atom induced by} \\ & \text{macroscopic electric field} \end{cases}$$

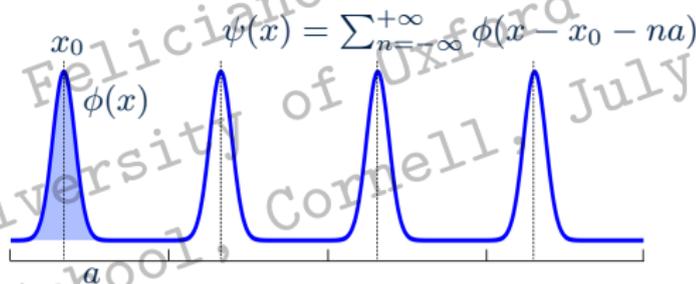
Most convenient for DFT calculations

MAPbI₃ (MA=CH₃NH₃)

	Nominal charge	Born charge tensor			Isotropic Born charge
Pb	+2	4.52	-0.14	-0.77	+4.42
		-0.19	4.42	0.60	
		0.66	-0.27	4.31	
I	-1	-0.58	0.00	0.08	-1.88
		0.01	-4.15	0.01	
		0.16	0.01	-0.92	

- A uniform electric field yields a potential which is unbounded in infinite crystals
 $V(x) = eEx \rightarrow \infty$ when $x \rightarrow \infty$
- Replace the position operator x by the **Berry-phase formula**
 R.D. King-Smith and D. Vanderbilt, Phys. Rev. B (R) 47, 1651 (1993)

Simplified model



$$\langle \psi | e^{i \frac{2\pi x}{L}} | \psi \rangle = e^{i \frac{2\pi x_0}{L}} \langle \psi | e^{i \frac{2\pi(x-x_0)}{L}} | \psi \rangle = e^{i \frac{2\pi x_0}{L}} [1 + A/L^2 + iB/L^3 + \dots]$$

$$\frac{L}{2\pi} \text{Im} \log \langle \psi | e^{i \frac{2\pi x}{L}} | \psi \rangle = x_0 \bmod L + \mathcal{O}(1/L^2)$$



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University of Oxford

Paradim School, Cornell, July 2016

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25–29 July 2016

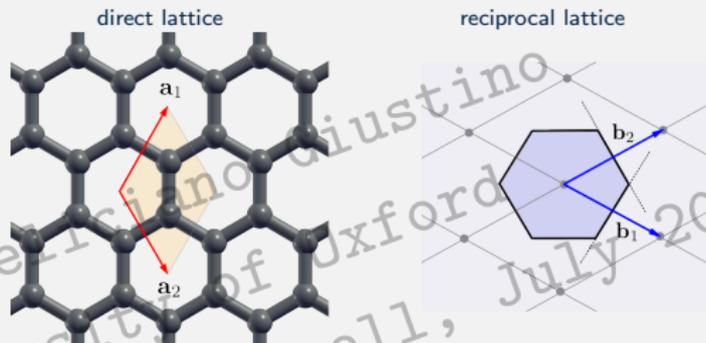


Lecture 5.1

Band structures & optical spectra

From Lecture 2.2

Example: graphene

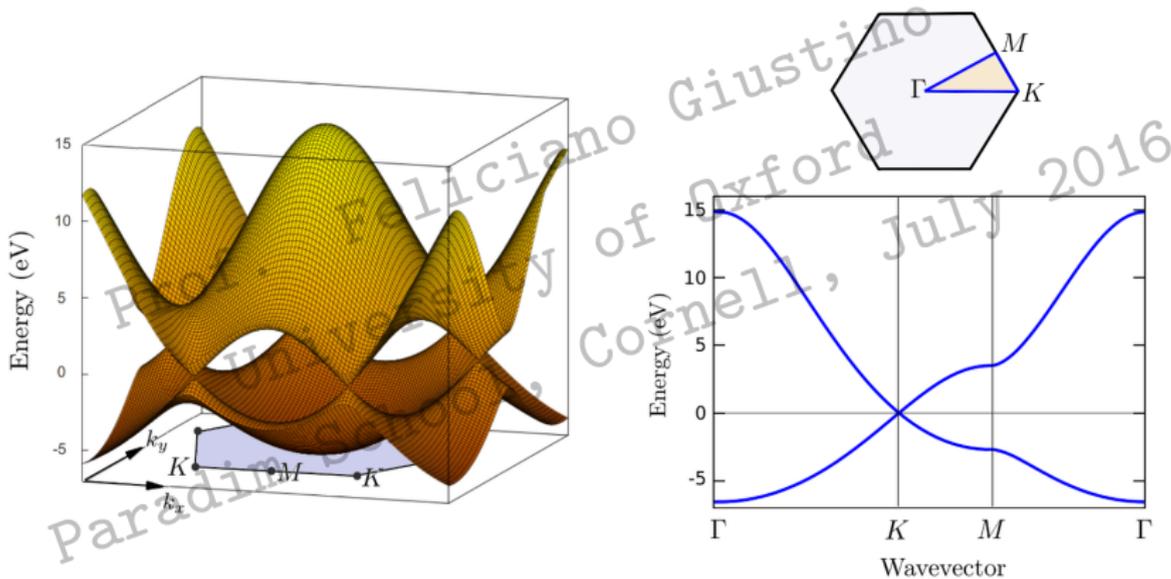


$$\phi_{i\mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k}\cdot\mathbf{r}} u_{i\mathbf{k}}(\mathbf{r}) \text{ with } u_{i\mathbf{k}}(\mathbf{r}) \text{ periodic}$$

$$-\frac{1}{2}\nabla^2\phi_{i\mathbf{k}}(\mathbf{r}) + V_{\text{tot}}(\mathbf{r})\phi_{i\mathbf{k}}(\mathbf{r}) = \epsilon_{i\mathbf{k}}\phi_{i\mathbf{k}}(\mathbf{r})$$

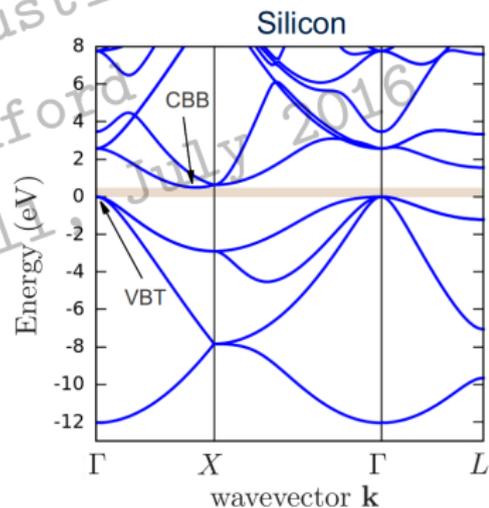
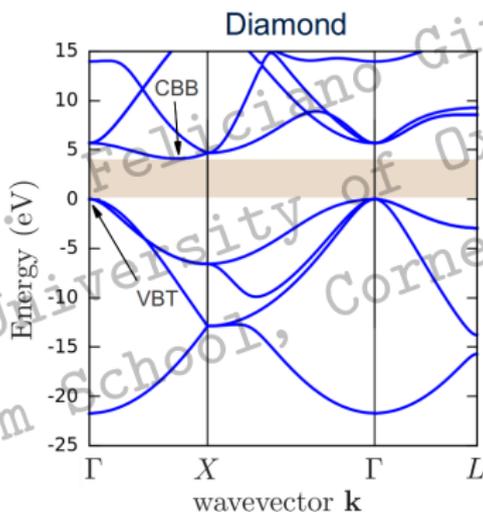
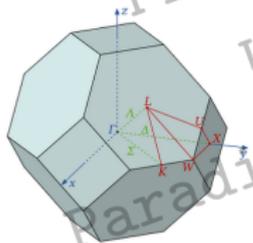
$\epsilon_{i\mathbf{k}}$
k-dependent
KS eigenvalue

Example: simplified tight-binding model of graphene



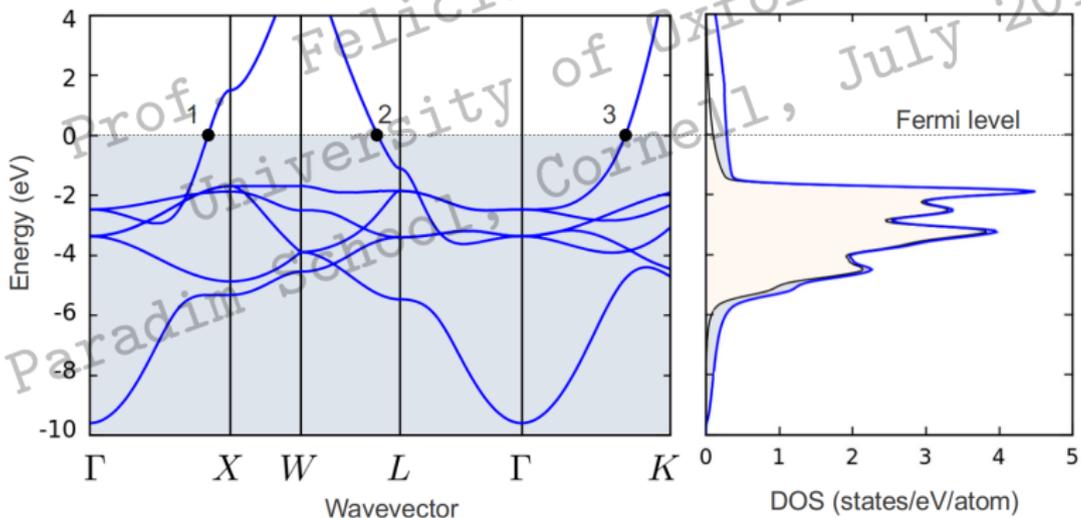
Example: DFT/LDA band structures of common semiconductors

	13 3A	14 4A	15 5A
5	B Boron 10.81	C Carbon 12.01	N Nitrogen 14.01
12 2B	Al Aluminum 26.98	Si Silicon 28.09	P Phosphorus 30.97
30	Ga Gallium 69.72	Ge Germanium 72.61	As Arsenic 74.92
48	49	50	51

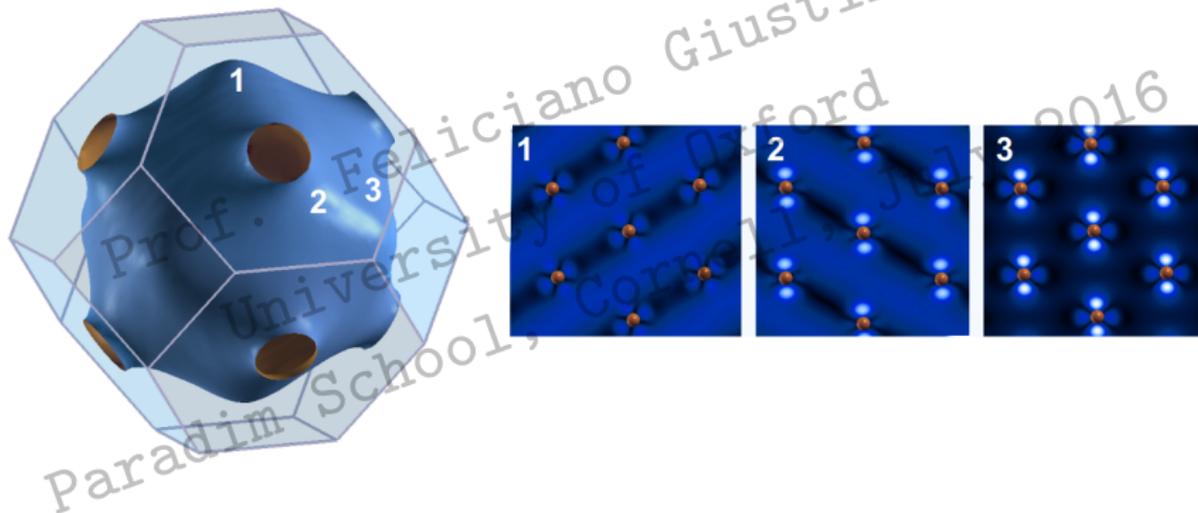


Example: DFT/LDA band structure and Density of States of copper

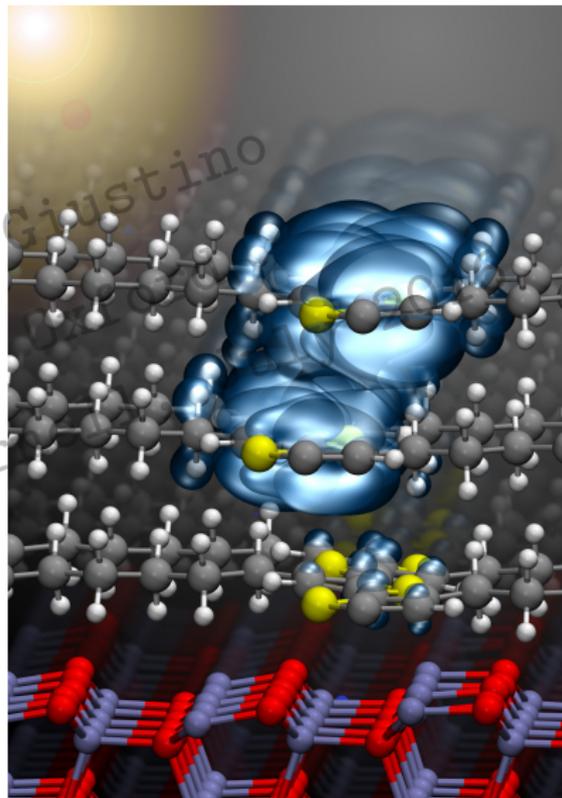
1	Lithium 6.94	Beryllium 9.01																	Boron 10.81
2	11 Na	12 Mg																	13 Al
3	Sodium 22.99	Magnesium 24.31	3 3B	4 4B	5 5B	6 6B	7 7B	8	9	10	11 1B	12 2B	Aluminum 26.98						
4	19 K	20 Ca	21 Sc	22 Ti	23 V	24 Cr	25 Mn	26 Fe	27 Co	28 Ni	29 Cu	30 Zn	31 Ga						
	Potassium 39.10	Calcium 40.08	Scandium 44.96	Titanium 47.87	Vanadium 50.94	Chromium 52.00	Manganese 54.94	Iron 55.85	Cobalt 58.93	Nickel 58.69	Copper 63.55	Zinc 65.39	Gallium 69.72						
5	37 Rb	38 Sr	39 Y	40 Zr	41 Nb	42 Mo	43 Tc	44 Ru	45 Rh	46 Pd	47 Ag	48 Cd	49 In						
	Rubidium 85.47	Strontium 87.62	Yttrium 88.91	Zirconium 91.22	Niobium 92.91	Molybdenum 95.94	Technetium 98.91	Ruthenium 101.07	Rhodium 102.91	Palladium 106.37	Silver 107.87	Cadmium 112.41	Indium 114.82						



Example: DFT/LDA Fermi surface and wavefunctions of copper



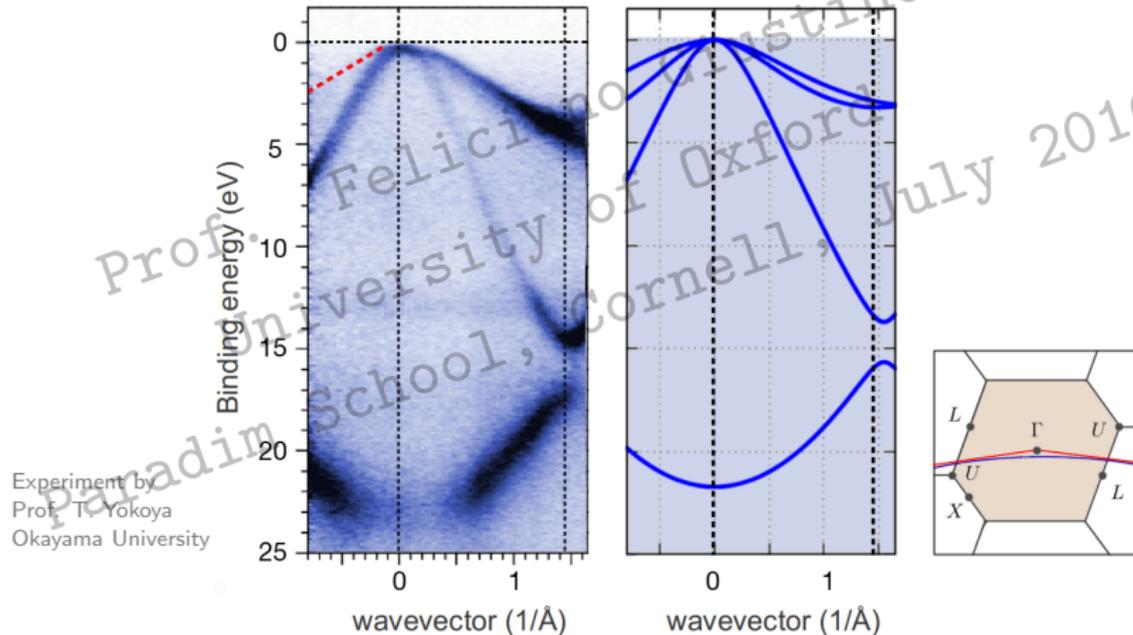
Example: Highest-occupied orbital
of P3HT on ZnO



Noori & Giustino, Adv. Func. Mater. 22, 5089 (2012)

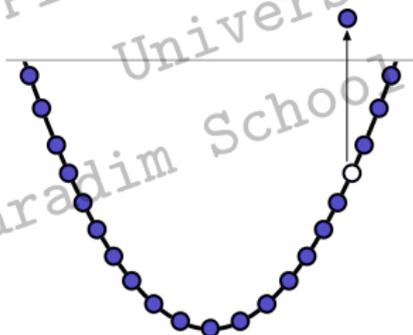
- Are band structures real?

ARPES spectrum of diamond and DFT/LDA bands



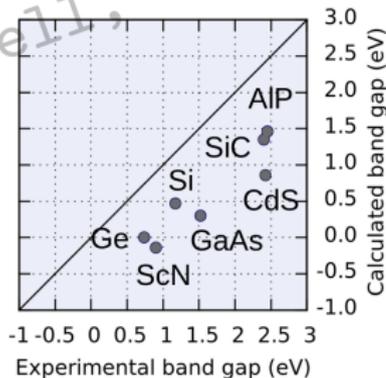
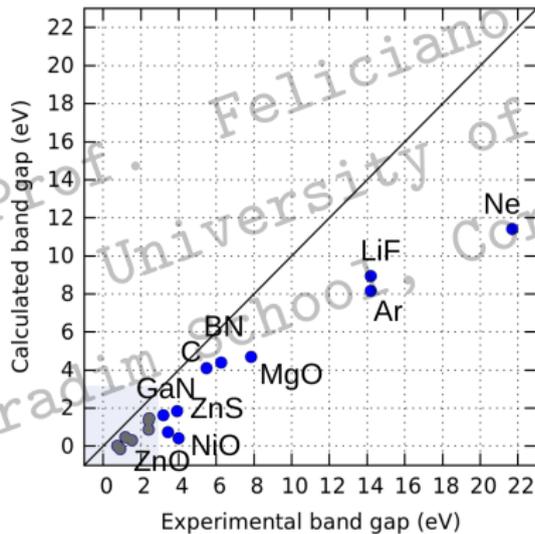
The DFT total energy (Lecture 2.1) can be rewritten as

$$E[n] = \underbrace{\sum_i \frac{dk}{\Omega_{\text{BZ}}} f_{i\mathbf{k}} \varepsilon_{i\mathbf{k}}}_{\substack{\text{band structure term} \\ f_{i\mathbf{k}} \text{ electron occupation}}} - \underbrace{\left[E_{\text{H}} + \int d\mathbf{r} V_{xc}(\mathbf{r})n(\mathbf{r}) - E_{xc} \right]}_{\text{double counting term}}$$



- If the double-counting term vanished, $\varepsilon_{i\mathbf{k}}$ would give the change of energy upon adding/removing one electron
- KS levels can be thought of as very rough approximations to addition/removal energies

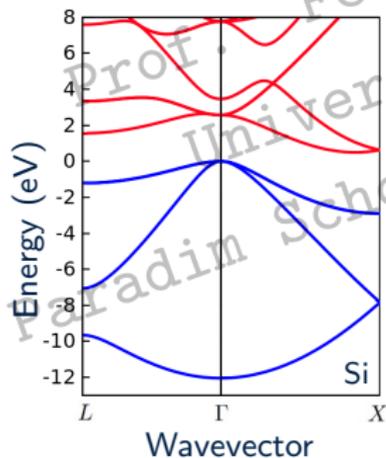
- DFT/LDA typically underestimates the band gaps of insulators and semiconductors
- Major challenge in materials design



From band structure & wavefunctions we can calculate UV/Vis spectra

$$\epsilon_2(\omega) = \frac{\pi e^2}{\epsilon_0 m_e^2 \Omega} \frac{1}{\omega^2} \sum_{cv} \int \frac{d\mathbf{k}}{\Omega_{\text{BZ}}} |\langle u_{c\mathbf{k}} | p_x | u_{v\mathbf{k}} \rangle|^2 \delta(\epsilon_{c\mathbf{k}} - \epsilon_{v\mathbf{k}} - \hbar\omega)$$

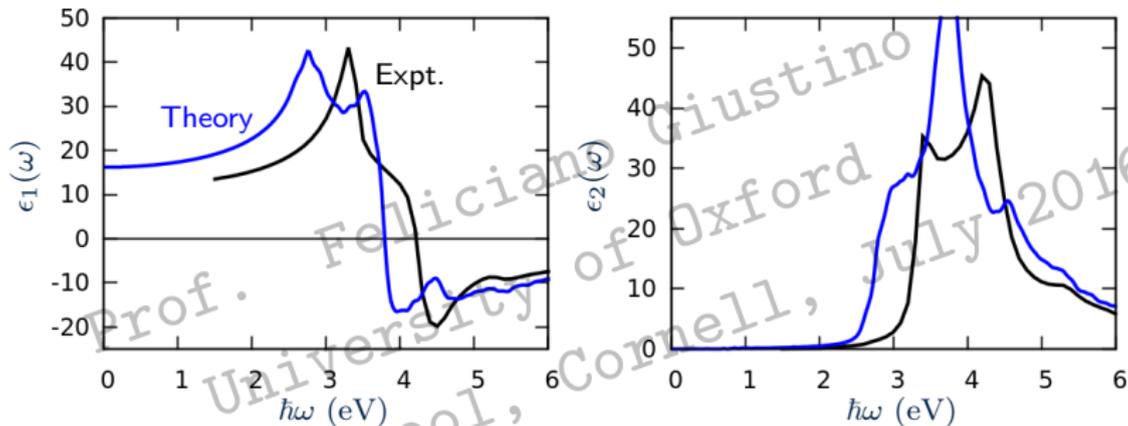
Independent-particle approximation



For a derivation see Chapter 10 of the Book

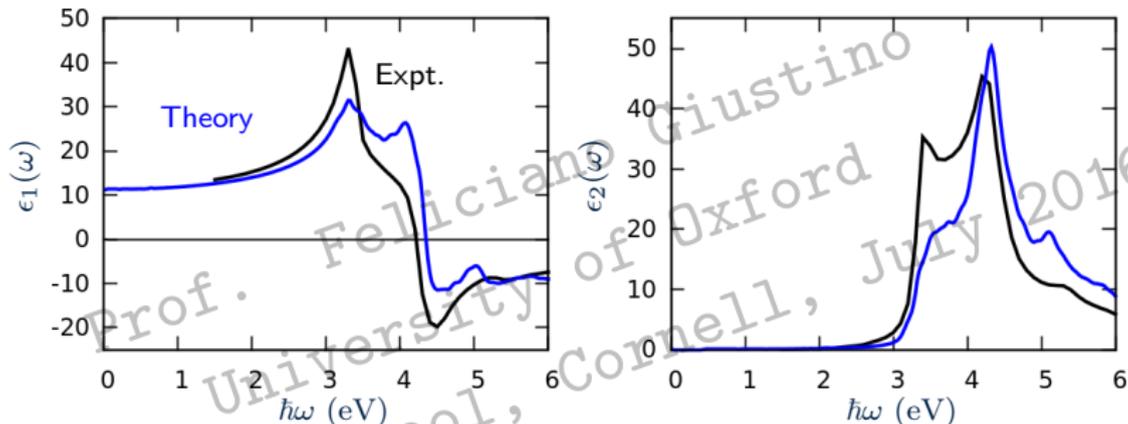
- Transitions from occupied to empty states
- Energy conservation
- Momentum conservation
- Oscillator strength given by electric dipole matrix element $\langle u_{c\mathbf{k}} | x | u_{v\mathbf{k}} \rangle$

Example: Dielectric function of silicon



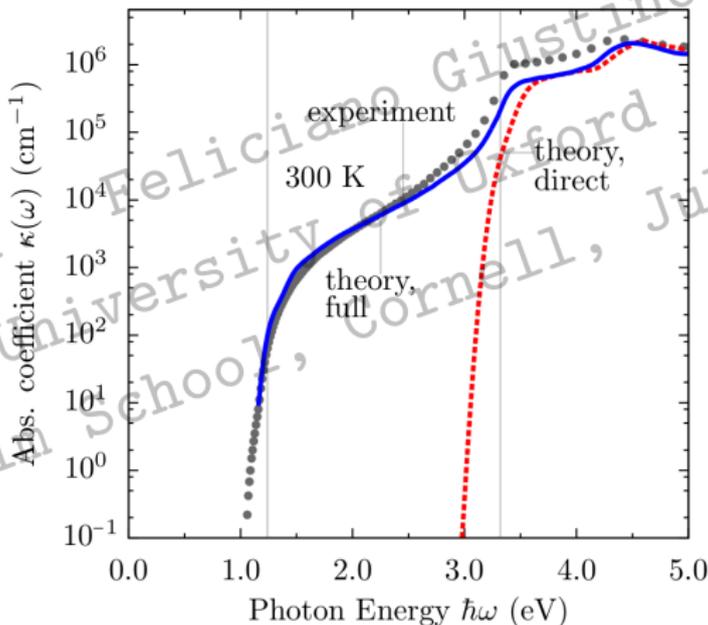
- DFT/LDA in the independent-particle approximation

Example: Dielectric function of silicon



- DFT/LDA in the independent-particle approximation
- 'Scissor correction' of 0.55 eV
- Excitonic peak observed at 3.2 eV missing in the calculation
- Phonon-assisted absorption below 3 eV missing in the calculation

Example: Optical absorption coefficient of silicon including phonon-assisted processes



Zacharias, Patrick & Giustino, PRL 2015



An introduction to density functional theory for experimentalists

Prof. Feliciano Giustino
University of Oxford

Paradim School, Cornell, July 2016

Feliciano Giustino

University of Oxford

25–29 July 2016



Lecture 5.2

DFT beyond the LDA

Prof. Feliciano Giustino
University of Oxford

Paradim School, Cornell, July 2016

Perdew, Burke & Ernzerhof, Phys. Rev. Lett. 77, 3865 (1996)

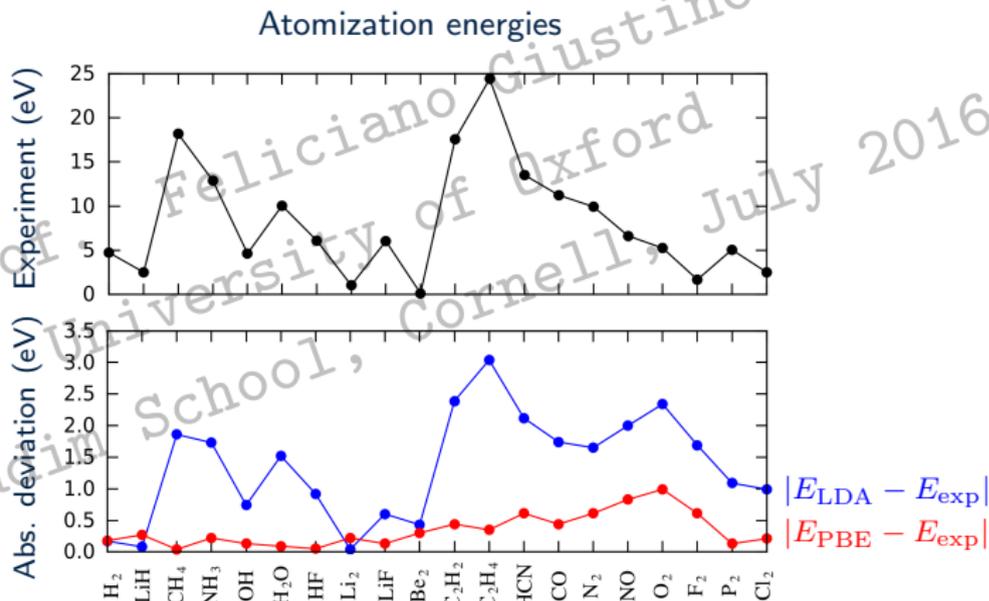
- Within the LDA the XC energy is approximated using the local density

$$E_{xc}^{\text{LDA}} = \int d\mathbf{r} n(\mathbf{r}) \epsilon_{xc}^{\text{HEG}}[n(\mathbf{r})]$$

- 'Generalized gradient' approximations (GGA) incorporate information about the density gradient

$$E_{xc}^{\text{GGA}} = \int d\mathbf{r} f[n(\mathbf{r}), \nabla n(\mathbf{r})]$$

Perdew, Burke & Ernzerhof, Phys. Rev. Lett. 77, 3865 (1996)



From Table 1 of Perdew, Burke, Ernzerhof, PRL 1996

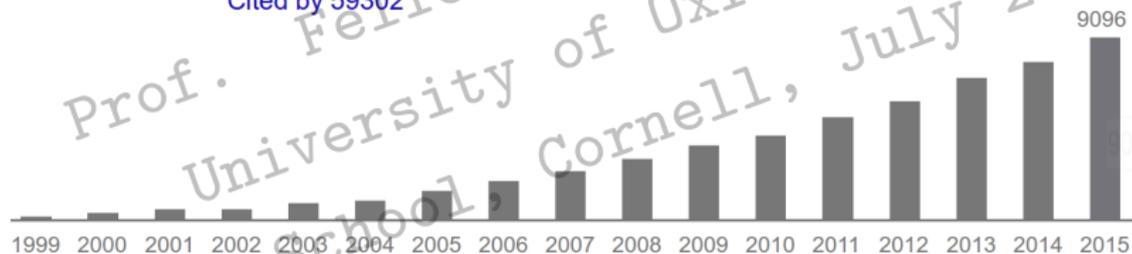
Perdew, Burke & Ernzerhof, Phys. Rev. Lett. 77, 3865 (1996)

Scholar articles

[Generalized gradient approximation made simple](#)

JP Perdew, K Burke, M Ernzerhof - Physical review letters, 1996

Cited by 59302



Anisimov, Zaanen & Andersen, Phys. Rev. B 44, 943 (1991)
Cococcioni & De Gironcoli, Phys. Rev. B 71, 035105 (2005)

1 H Hydrogen 1.01																	2 He Helium 4.00						
3 Li Lithium 6.94	4 Be Beryllium 9.01																	5 B Boron 10.81	6 C Carbon 12.01	7 N Nitrogen 14.01	8 O Oxygen 16.00	9 F Fluorine 19.00	10 Ne Neon 20.18
11 Na Sodium 22.99	12 Mg Magnesium 24.31																	13 Al Aluminum 26.98	14 Si Silicon 28.09	15 P Phosphorus 30.97	16 S Sulfur 32.07	17 Cl Chlorine 35.45	18 Ar Argon 39.95
19 K Potassium 39.10	20 Ca Calcium 40.08	21 Sc Scandium 44.96	22 Ti Titanium 47.87	23 V Vanadium 50.94	24 Cr Chromium 51.99	25 Mn Manganese 54.94	26 Fe Iron 55.85	27 Co Cobalt 58.93	28 Ni Nickel 58.69	29 Cu Copper 63.55	30 Zn Zinc 65.38	31 Ga Gallium 69.72	32 Ge Germanium 72.61	33 As Arsenic 74.92	34 Se Selenium 78.96	35 Br Bromine 79.90	36 Kr Krypton 83.80						
37 Rb Rubidium 85.47	38 Sr Strontium 87.62	39 Y Yttrium 88.91	40 Zr Zirconium 91.22	41 Nb Niobium 92.91	42 Mo Molybdenum 95.94	43 Tc Technetium (98)	44 Ru Ruthenium 101.07	45 Rh Rhodium 101.07	46 Pd Palladium 106.42	47 Ag Silver 107.87	48 Cd Cadmium 112.41	49 In Indium 114.82	50 Sn Tin 118.71	51 Sb Antimony 121.76	52 Te Tellurium 127.60	53 I Iodine 126.91	54 Xe Xenon 131.29						
55 Cs Cesium 132.91	56 Ba Barium 137.33	57 La Lanthanum 138.91	58 Ce Cerium 140.12	59 Pr Praseodymium 140.91	60 Nd Neodymium 144.24	61 Pm Promethium (145)	62 Sm Samarium 150.36	63 Eu Europium 151.96	64 Gd Gadolinium 157.25	65 Tb Terbium 158.93	66 Dy Dysprosium 162.50	67 Ho Holmium 164.93	68 Er Erbium 167.26	69 Tm Thulium 168.93	70 Yb Ytterbium 173.05	71 Lu Lutetium 174.97							
87 Fr Francium (223)	88 Ra Radium (226)	89 Ac Actinium (227)	90 Th Thorium (232)	91 Pa Protactinium (231)	92 U Uranium (238)	93 Np Neptunium (237)	94 Pu Plutonium (244)	95 Am Americium (243)	96 Cm Curium (247)	97 Bk Berkelium (247)	98 Cf Californium (251)	99 Es Einsteinium (252)	100 Fm Fermium (257)	101 Md Mendelevium (258)	102 No Nobelium (259)	103 Lr Lawrencium (260)							

- **3d transition metal** and **4f rare earth**
- LDA underestimates the on-site Coulomb energy between electrons
- DFT+*U* adds Hubbard-like corrections to remedy this deficiency
- Important for strongly-correlated materials

Anisimov, Zaanen & Andersen, Phys. Rev. B 44, 943 (1991)
Cococcioni & De Gironcoli, Phys. Rev. B 71, 035105 (2005)

FeO (AF-II phase)

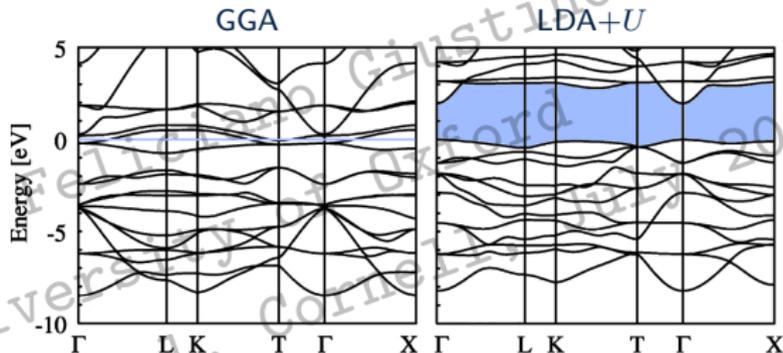
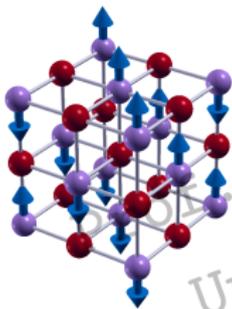


Figure from: Cococcioni & De Gironcoli, PRB 2005

- Computationally efficient
- Hubbard U often used as an adjustable parameter
- Results can be very sensitive to U

PBE0: Perdew, Burke & Ernzerhof, J. Chem. Phys. 105 (1996)

HSE: Heyd, Scuseria & Ernzerhof, J. Chem. Phys. 118, 8207 (2003)

- Improve upon semilocal GGA by including fully non-local Fock exchange [see Lecture 1.2, slide 14]

$$E_x^{\text{HF}} = - \sum_{j \in \text{occ}} \int d\mathbf{r}_1 d\mathbf{r}_2 \frac{\phi_i^*(\mathbf{r}_1) \phi_j^*(\mathbf{r}_2) \phi_i(\mathbf{r}_2) \phi_j(\mathbf{r}_1)}{|\mathbf{r}_1 - \mathbf{r}_2|}$$

- PBE0 prescription

$$E_{xc}^{\text{PBE0}} = \frac{3}{4} E_x^{\text{PBE}} + \frac{1}{4} E_x^{\text{F}} + E_c^{\text{PBE}}$$

- Requires the evaluation of the non-local Fock exchange potential \rightarrow Very expensive

$$V_X(\mathbf{r}, \mathbf{r}') = - \sum_{j \in \text{occ}} \frac{\phi_j(\mathbf{r}) \phi_j^*(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|}$$

PBE0: Perdew, Burke & Ernzerhof, J. Chem. Phys. 105 (1996)

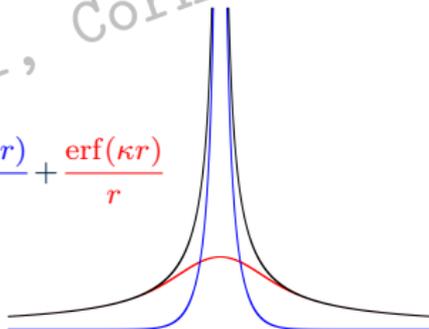
HSE: Heyd, Scuseria & Ernzerhof, J. Chem. Phys. 118, 8207 (2003)

- HSE prescription: separate short-range and long-range coulomb interactions

$$E_{xc}^{\text{HSE}} = \left[\frac{3}{4} E_x^{\text{PBE, sr}} + \frac{1}{4} E_x^{\text{F, sr}} \right] + E_x^{\text{PBE, lr}} + E_c^{\text{PBE}}$$

- The separation is carried out by breaking the Coulomb potential in two parts

$$\frac{1}{r} = \frac{\text{erfc}(\kappa r)}{r} + \frac{\text{erf}(\kappa r)}{r}$$



PBE0: Perdew, Burke & Ernzerhof, J. Chem. Phys. 105 (1996)

HSE: Heyd, Scuseria & Ernzerhof, J. Chem. Phys. 118, 8207 (2003)

- **Band gaps**

Typically PBE underestimates band gaps while Hartree-Fock overestimates. Mixing PBE and HF yields values closer to experiment

- **Exchange fraction**

Widespread practice of using the mixing fraction as an adjustable empirical parameter

- **Correlation**

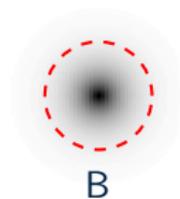
The correlation energy is still described at the PBE level. This misses van der Waals corrections (slide 13) and dynamical effects (slide 14)

Example: Two H atoms far away from each other

- Electronic ground-state wavefunction for non-interacting atoms

$$\Psi_0(\mathbf{r}_1, \mathbf{r}_2) = \phi_{1s}^A(\mathbf{r}_1) \phi_{1s}^B(\mathbf{r}_2)$$

- Electron density



- This is (roughly) what we would obtain within DFT/LDA

Example: Two H atoms far away from each other

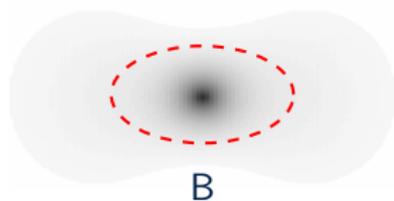
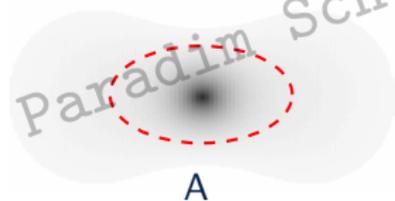
- We can obtain a lower-energy wavefunction by using

[Exercise 4.5 of Book]

$$\Psi(\mathbf{r}_1, \mathbf{r}_2) = \Psi_0(\mathbf{r}_1, \mathbf{r}_2) + \frac{\alpha/4\pi\epsilon_0}{d^3} \phi_{2p_x}^A(\mathbf{r}_1) \phi_{2p_x}^B(\mathbf{r}_2)$$

α = atomic polarizability

- The ground-state electron density is polarized



Example: Two H atoms far away from each other

- The density redistribution leads to an additional attractive potential energy between the nuclei, the **van der Waals interaction**

$$U = -\frac{C}{d^6}$$

- Not included in standard DFT
- Important for graphitic materials, biological systems, molecular crystals

Andersson, Langreth & Lundqvist, Phys. Rev. Lett. 76, 102 (1996)

Dion, Rydberg, Schröder, Langreth & Lundqvist, Phys. Rev. Lett. 92, 246401 (2004)

Grimme, J. Comp. Chem. 27, 1787 (2006)

Tkatchenko & Scheffler, Phys. Rev. Lett. 102, 073005 (2009)

The GW method

Hedin & Lundqvist, Solid State Physics 23, 1 (1969)

Hybertsen & Louie, Phys Rev B 34, 5390 (1986)

$$\text{KS} \quad -\frac{1}{2}\nabla^2\phi_i(\mathbf{r}) + [V_n(\mathbf{r}) + V_H(\mathbf{r})]\phi_i(\mathbf{r}) + V_{xc}(\mathbf{r})\phi_i(\mathbf{r}) = \varepsilon_i\phi_i(\mathbf{r})$$

$$\text{GW} \quad -\frac{1}{2}\nabla^2\phi_i(\mathbf{r}) + [V_n(\mathbf{r}) + V_H(\mathbf{r})]\phi_i(\mathbf{r}) + \int d\mathbf{r}' \Sigma(\mathbf{r}, \mathbf{r}', \varepsilon_i)\phi_i(\mathbf{r}') = \varepsilon_i\phi_i(\mathbf{r})$$

$$\Sigma = GW$$



Screened Coulomb interaction

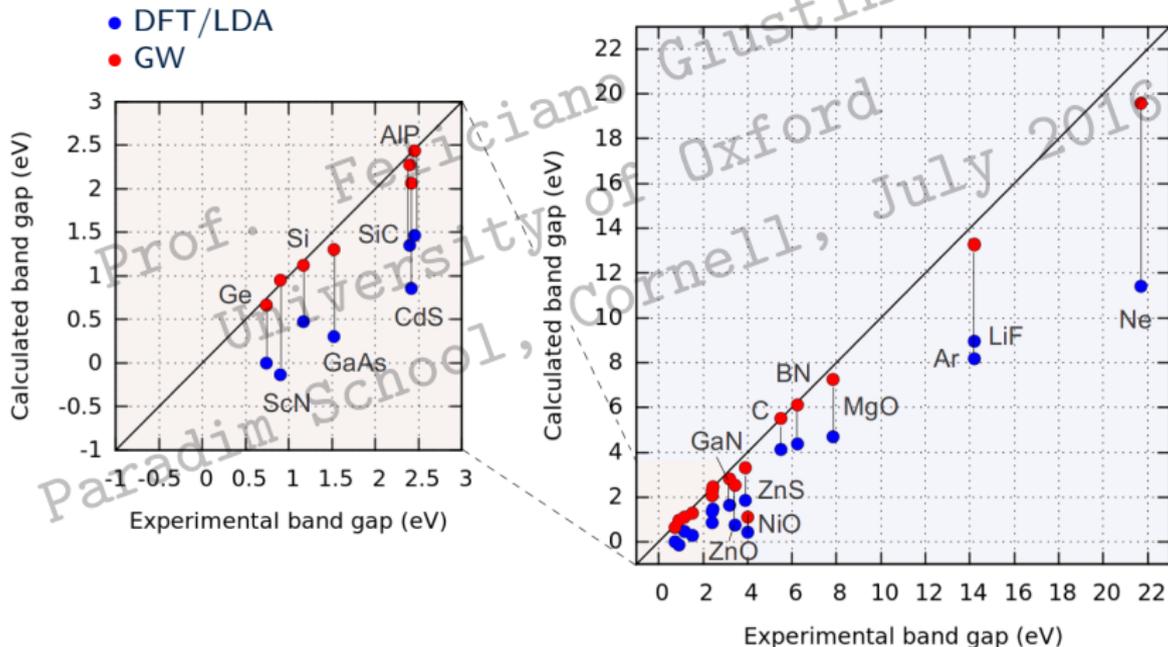
Electron Green's function

- Based on quantum-field theory
- Mostly used to correct KS eigenvalues
- Scales as N^4 (N number of atoms)

The GW method

Hedin & Lundqvist, Solid State Physics 23, 1 (1969)

Hybertsen & Louie, Phys Rev B 34, 5390 (1986)



Bethe-Salpeter approach

G. Strinati, Phys. Rev. B 29, 5718 (1984)

Onida, Reining & Rubio, Rev. Mod. Phys. 74, 601 (2002)

Rohlfing & Louie, Phys. Rev. Lett. 81. 2312 (1998)

- Excited states described as coherent superposition of electron-hole excitations

$$|S\rangle = \sum_{cv\mathbf{k}} A_{cv\mathbf{k}}^S \hat{a}_{v\mathbf{k}}^\dagger \hat{b}_{c\mathbf{k}+\mathbf{Q}}^\dagger |0\rangle$$

- Bethe-Salpeter equation (BSE)

$$(\varepsilon_{c\mathbf{k}+\mathbf{Q}} - \varepsilon_{v\mathbf{k}}) A_{cv\mathbf{k}}^S + \sum_{c'v'\mathbf{k}'} \langle cv\mathbf{k} | K^{\text{eh}} | c'v'\mathbf{k}' \rangle A_{c'v'\mathbf{k}'}^S = E_S A_{cv\mathbf{k}}^S$$

- The eigenvalues E_S yield the energies of electron-hole excitations (eg excitons)
- Used in combination with the GW method

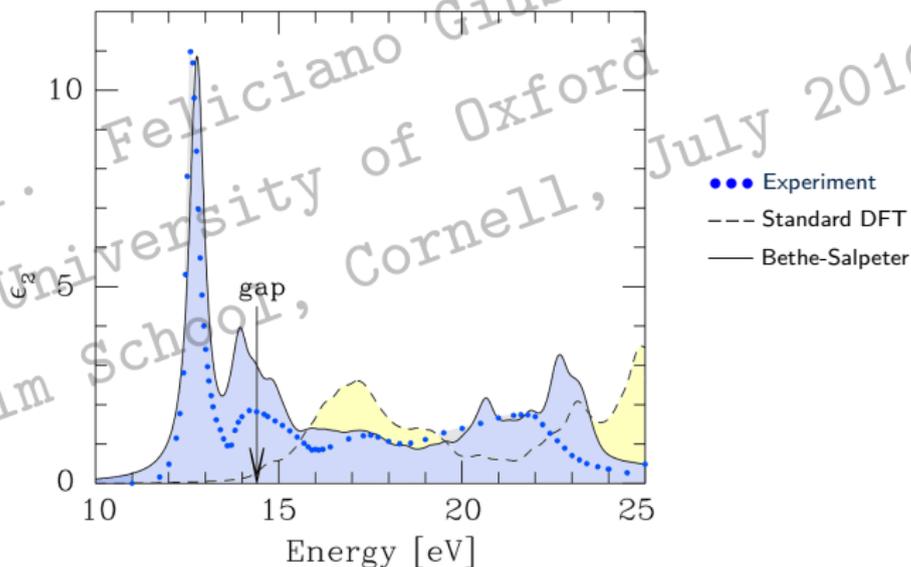
Bethe-Salpeter approach

Example: Optical absorption of LiF

G. Strinati, Phys. Rev. B 29, 5718 (1984)

Onida, Reining & Rubio, Rev. Mod. Phys. 74, 601 (2002)

Rohlfing & Louie, Phys. Rev. Lett. 81, 2312 (1998)



From: Rohlfing & Louie, Phys. Rev. Lett. 81, 2312 (1998)